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Matsusue et al.

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(54) **ORGANIC EL DISPLAY PANEL WITH SECOND BLUE EMITTER, DISPLAY DEVICE PROVIDED THEREWITH, AND METHOD FOR MANUFACTURING ORGANIC EL DISPLAY PANEL**

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This patent is subject to a terminal disclaimer.

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H01L 27/3211; **H01L 51/0008**;
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Primary Examiner — Michael Jung

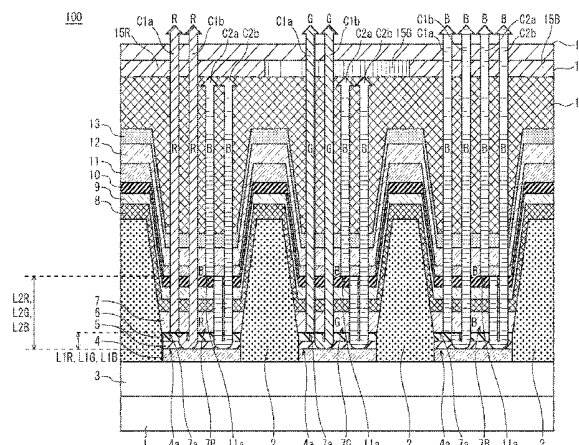
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(57) **ABSTRACT**

An organic EL display panel that includes light-reflective electrodes, a red light-emitting layer, a green light-emitting layer, a first blue light-emitting layer, a charge generating layer, a second blue light-emitting layer, and a light-transmissive electrode. In a red sub-pixel region, a first optical length is from 20 nm to 50 nm, and a second optical length is from 210 nm to 230 nm. In a green sub-pixel region, the first optical length is from 20 nm to 50 nm, and the second optical length is from 240 nm to 295 nm. In a blue sub-pixel

(Continued)



region, the first optical length is from 20 nm to 60 nm, and the second optical length is from 195 nm to 205 nm.

H01L 2251/558; H01L 2251/5315; H01L 2251/533

See application file for complete search history.

9 Claims, 16 Drawing Sheets

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H01L 51/56 (2006.01)
H01L 51/00 (2006.01)
- (52) **U.S. Cl.**
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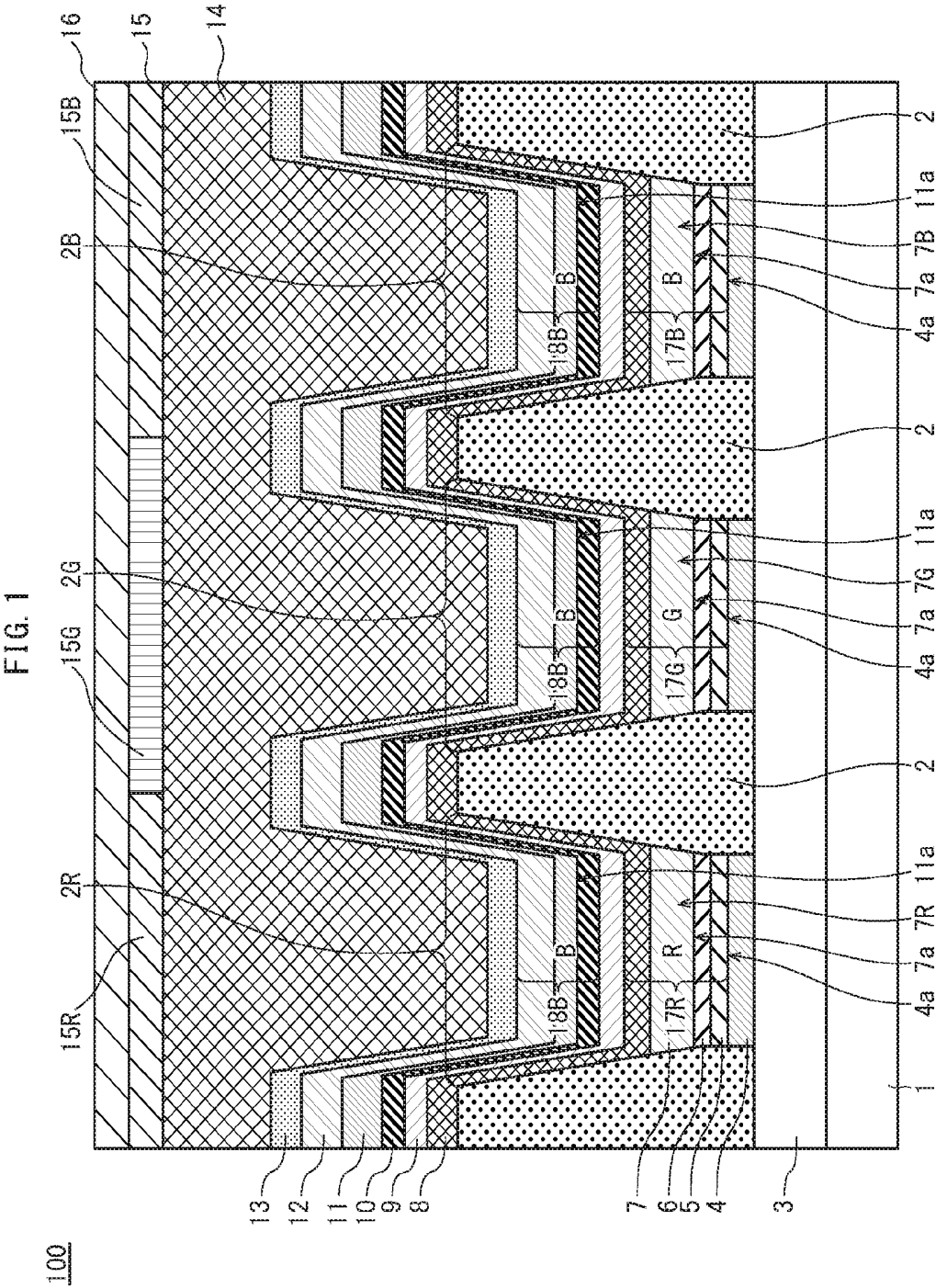


FIG. 2

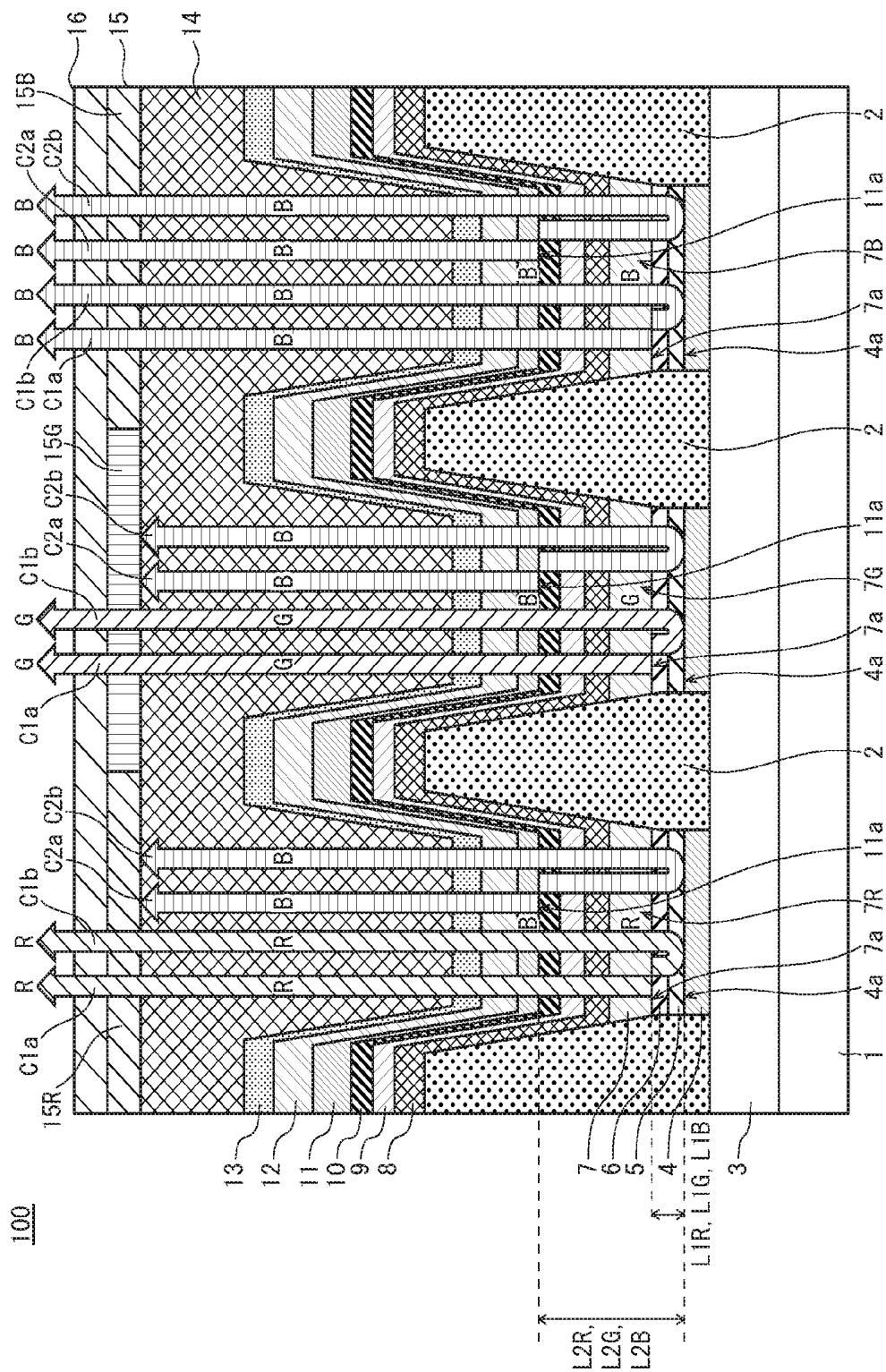


FIG. 3A

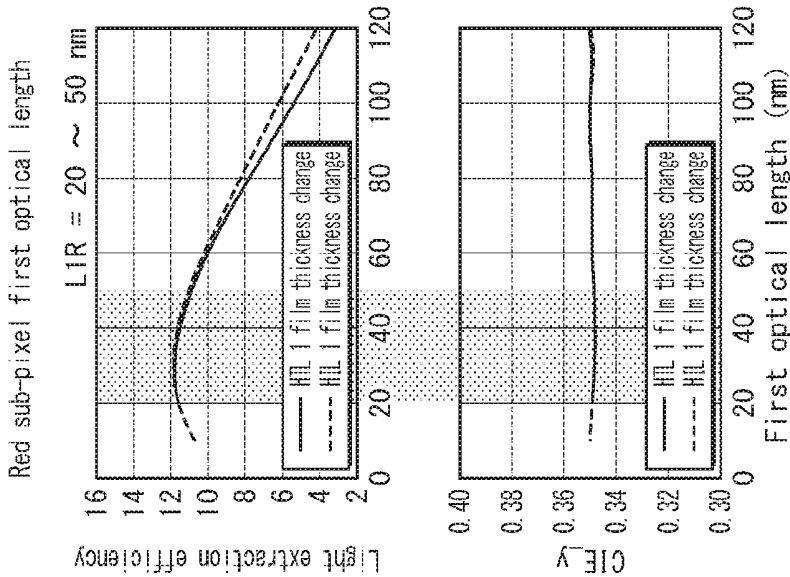


FIG. 3B

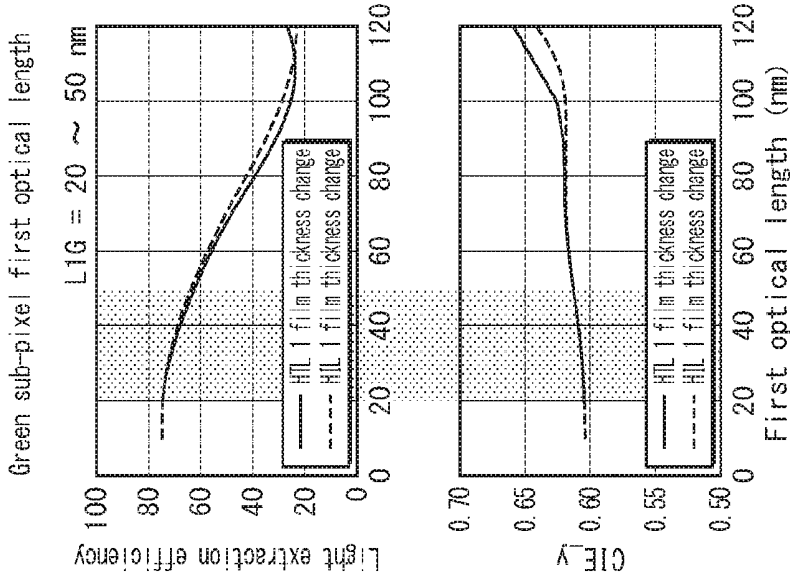


FIG. 3C

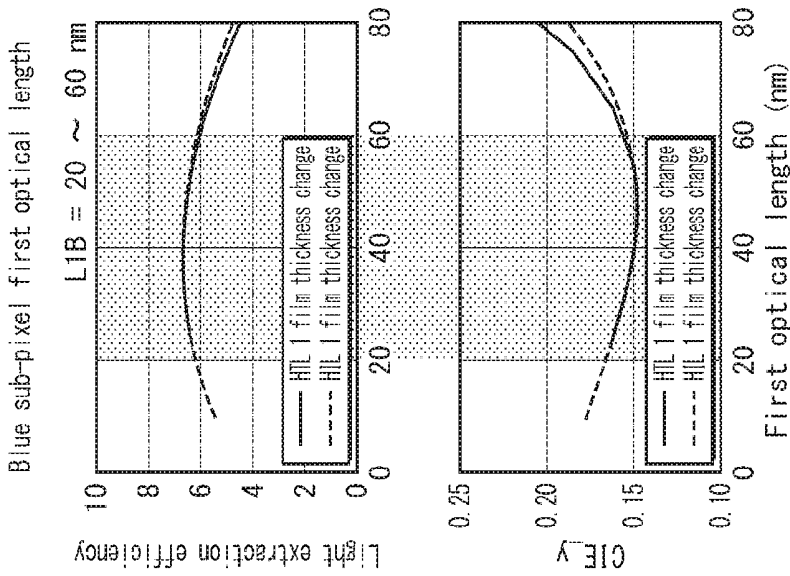


FIG. 4A

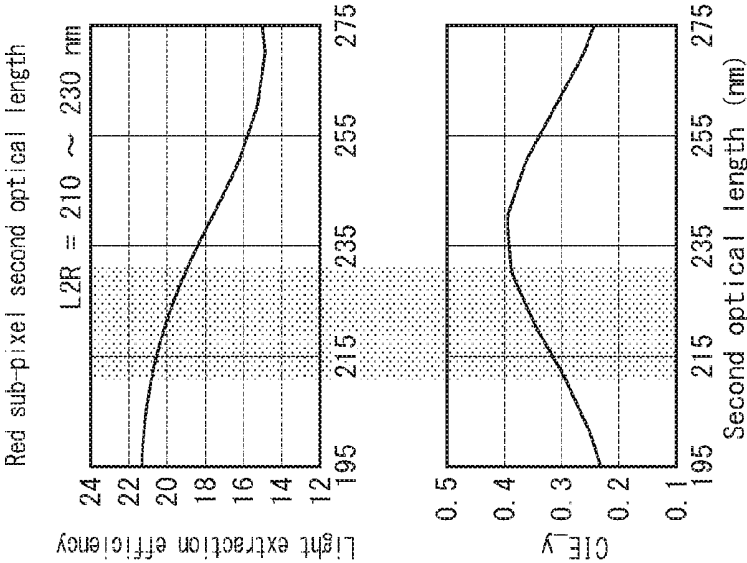


FIG. 4B

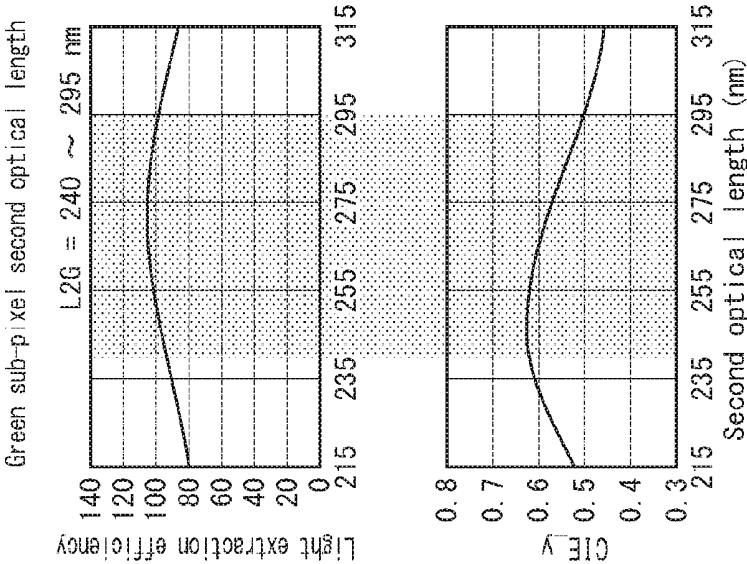


FIG. 4C

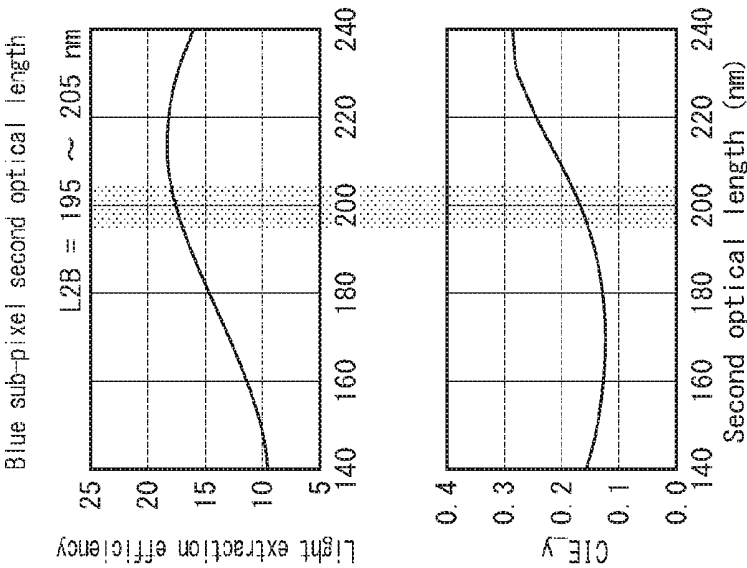


FIG. 5

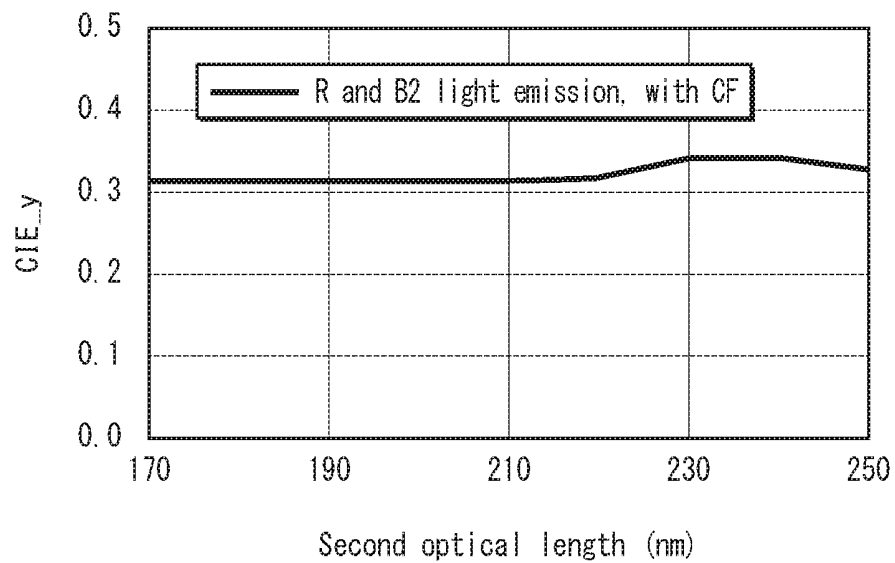
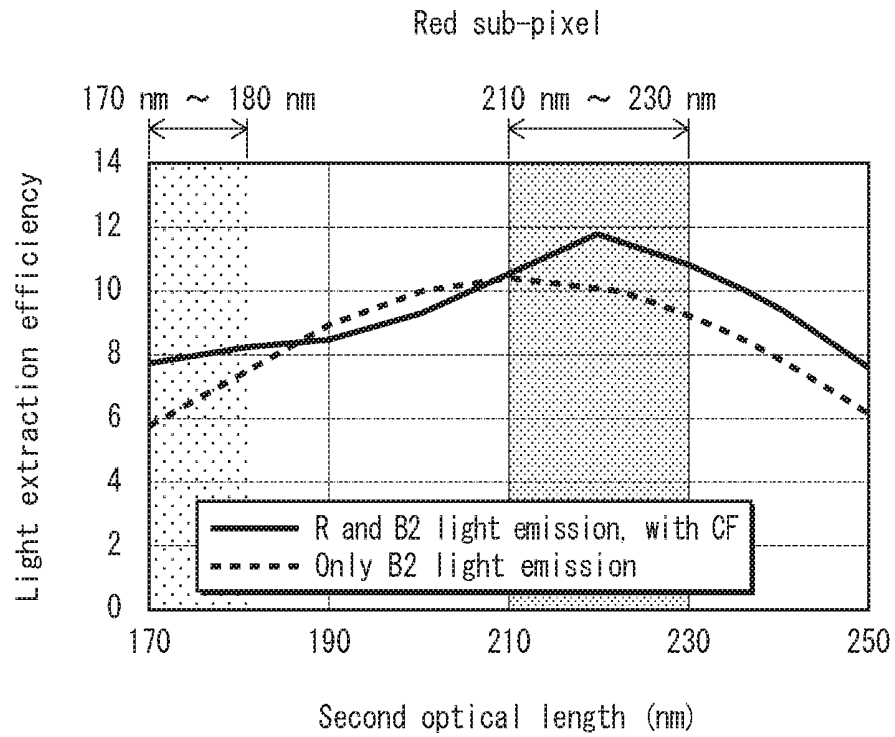


FIG. 6

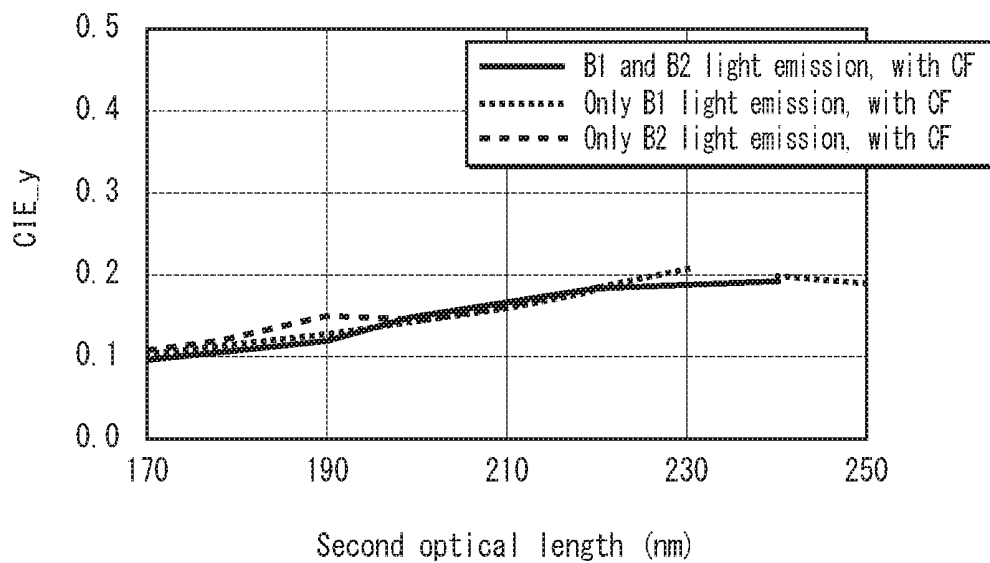
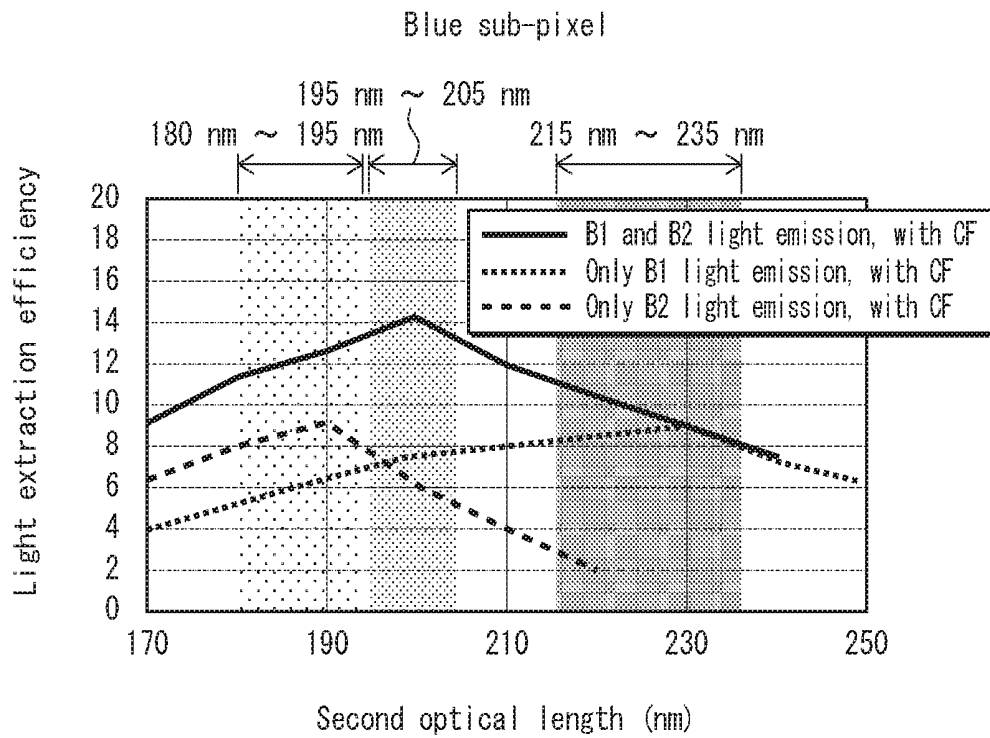


FIG. 7A

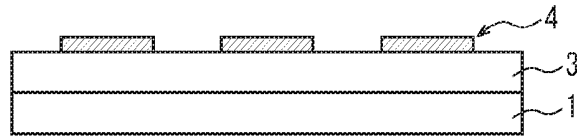


FIG. 7B

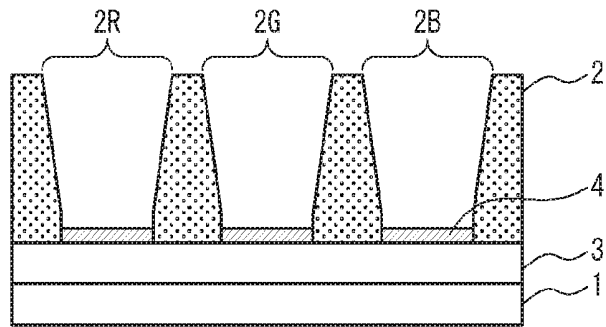


FIG. 7C

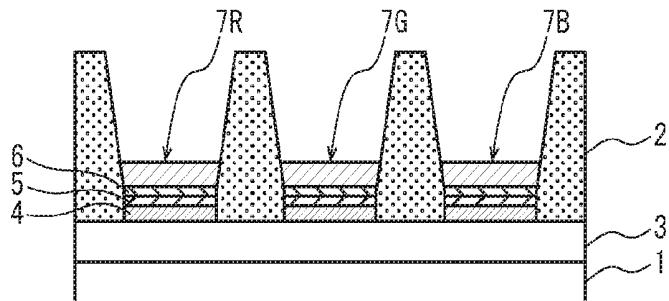


FIG. 7D

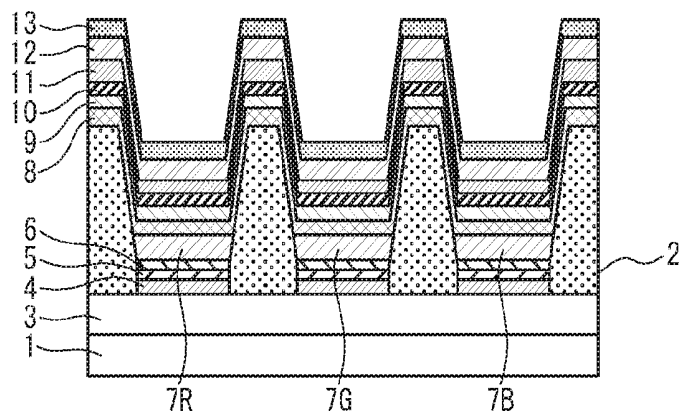
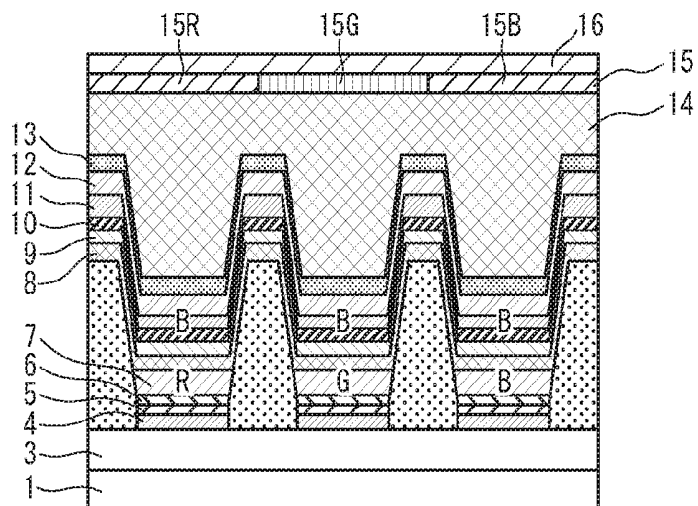


FIG. 7E



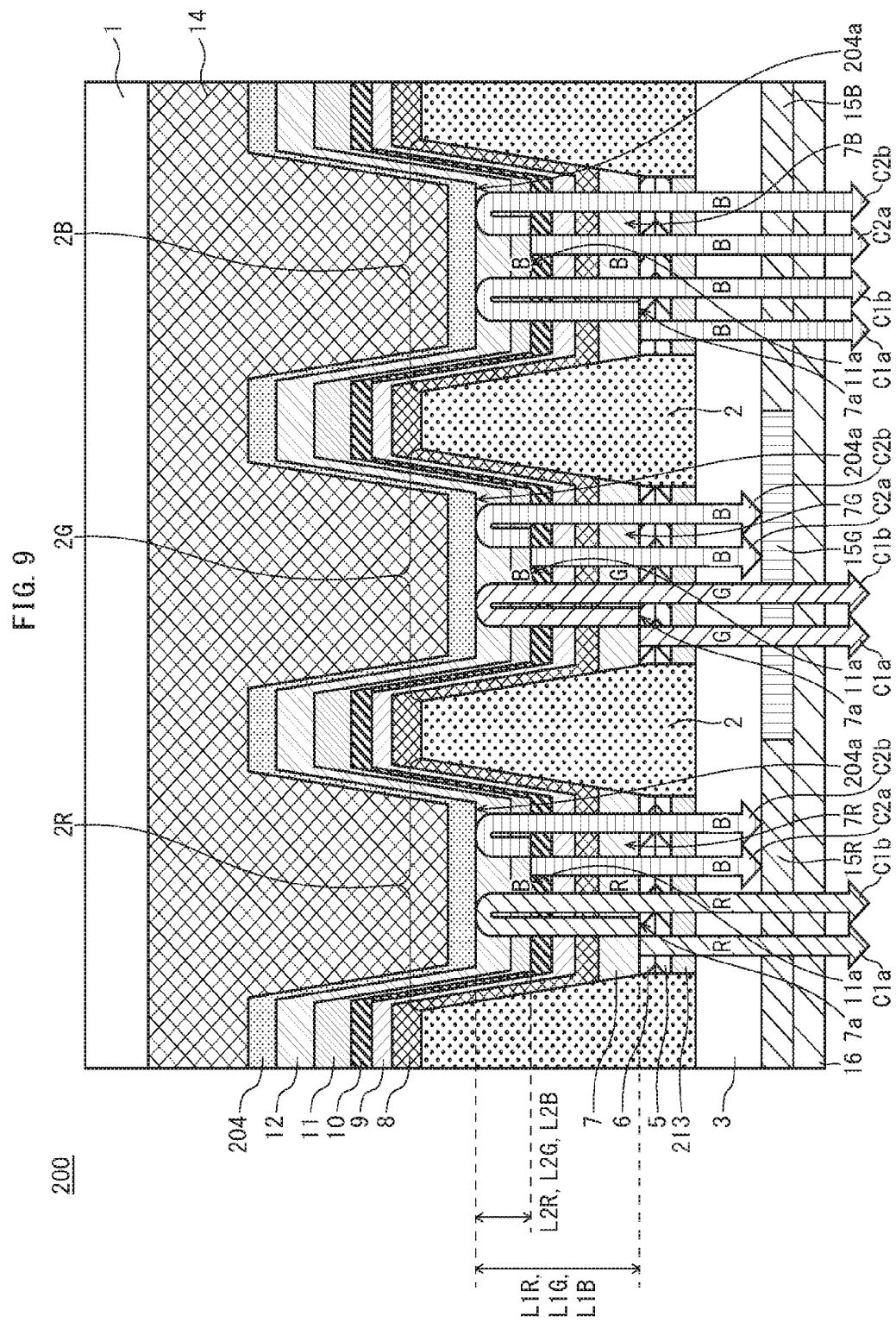


FIG. 10

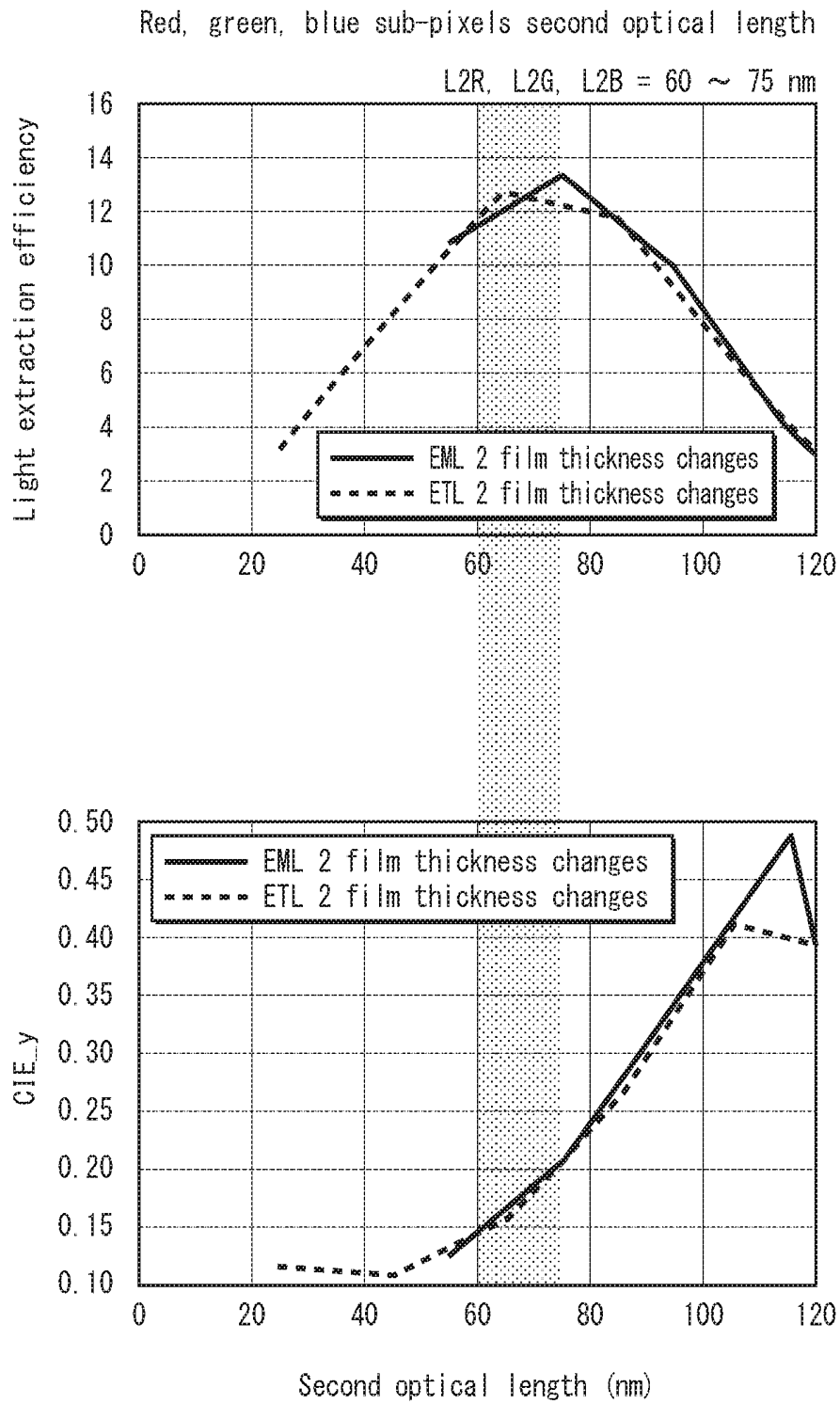


FIG. 11A

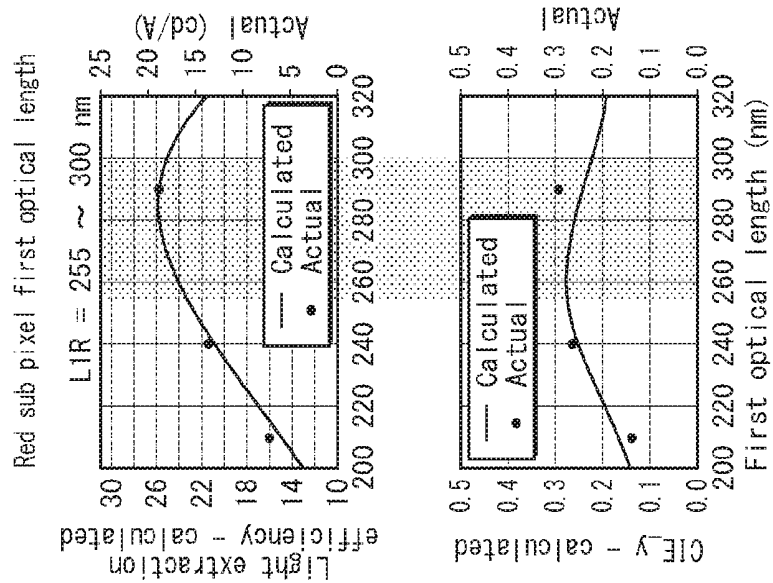


FIG. 11B

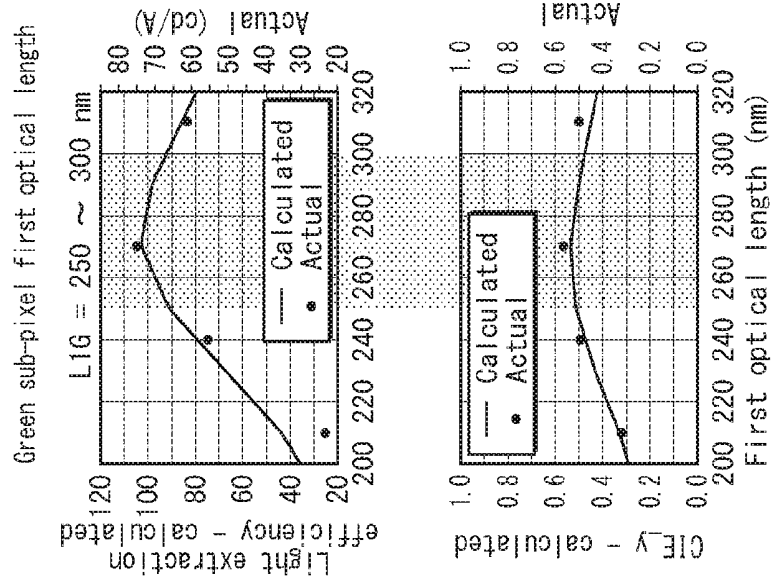


FIG. 11C

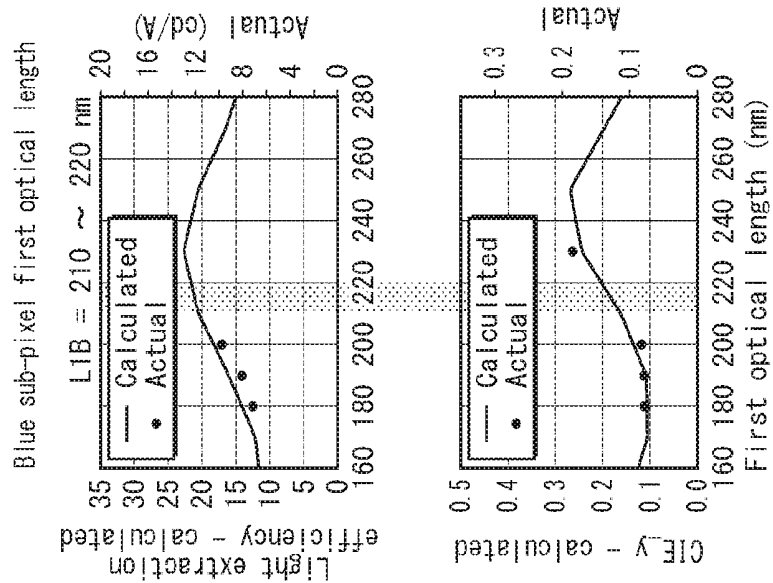


FIG. 12A

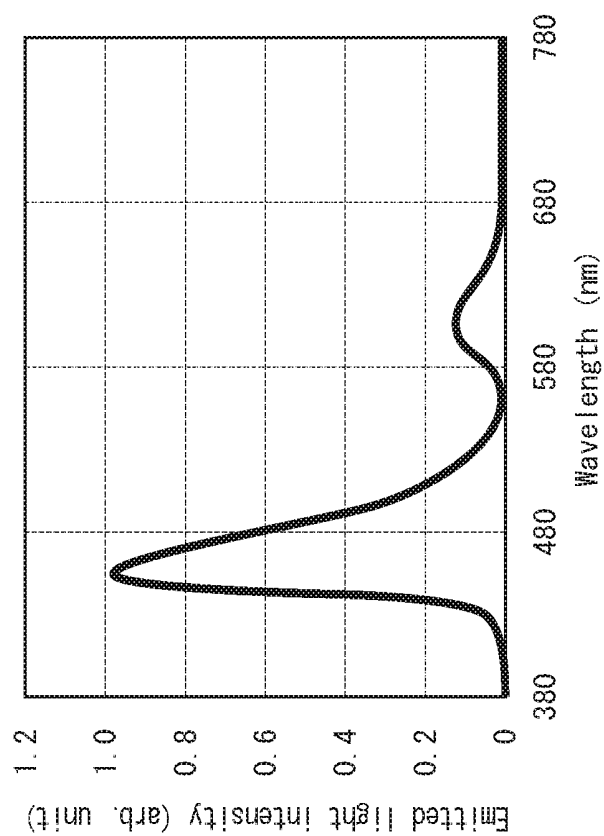


FIG. 12B

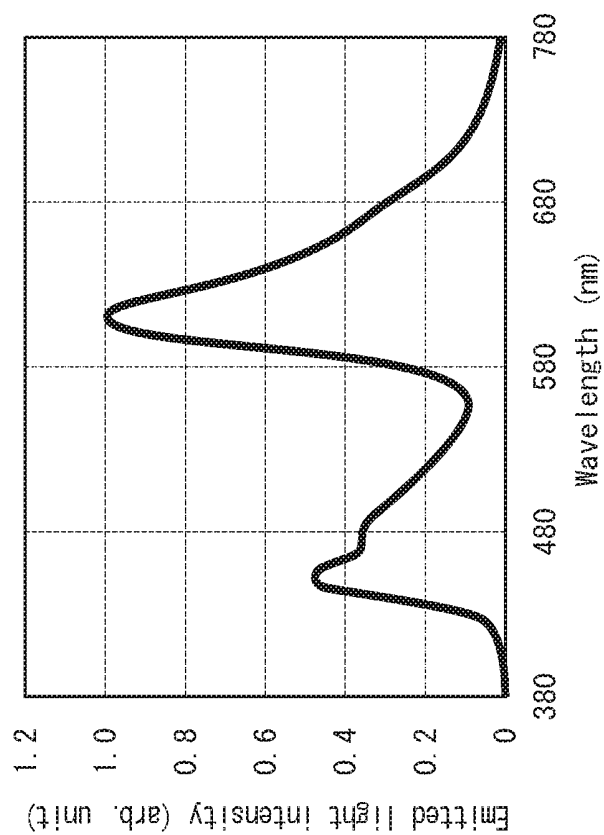


FIG. 13

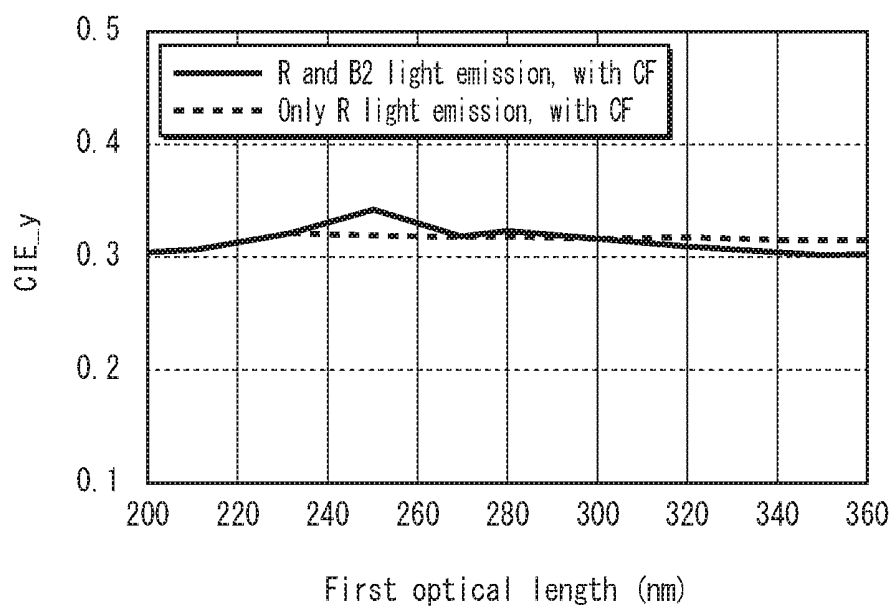
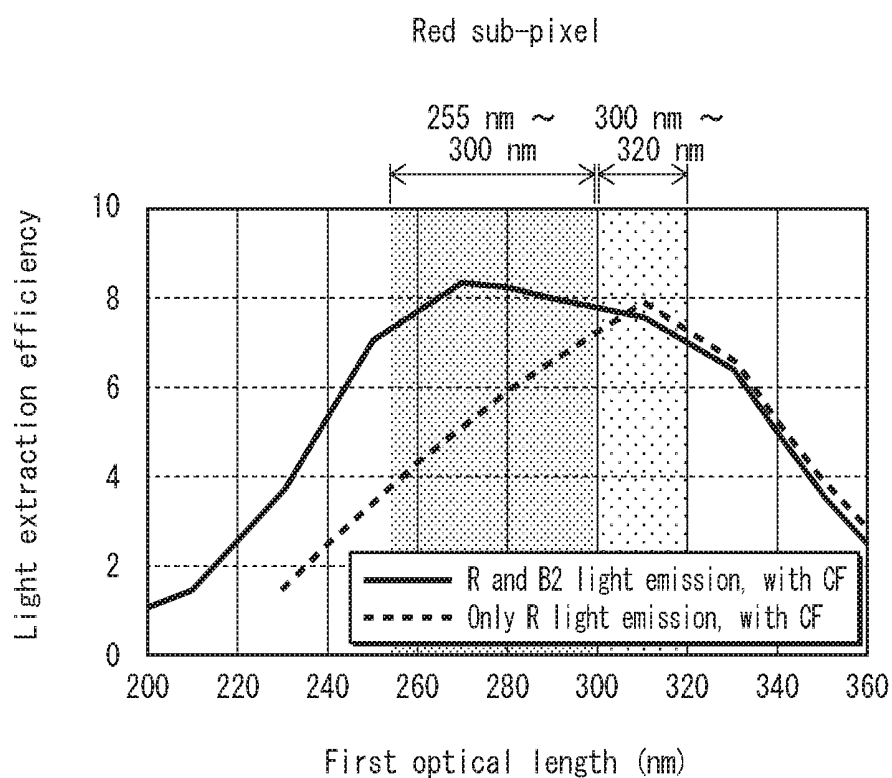


FIG. 14

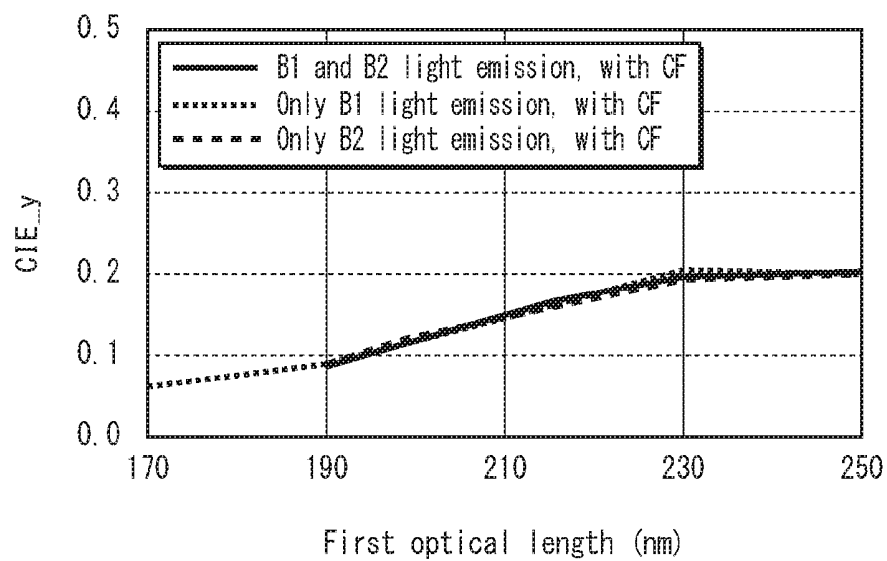
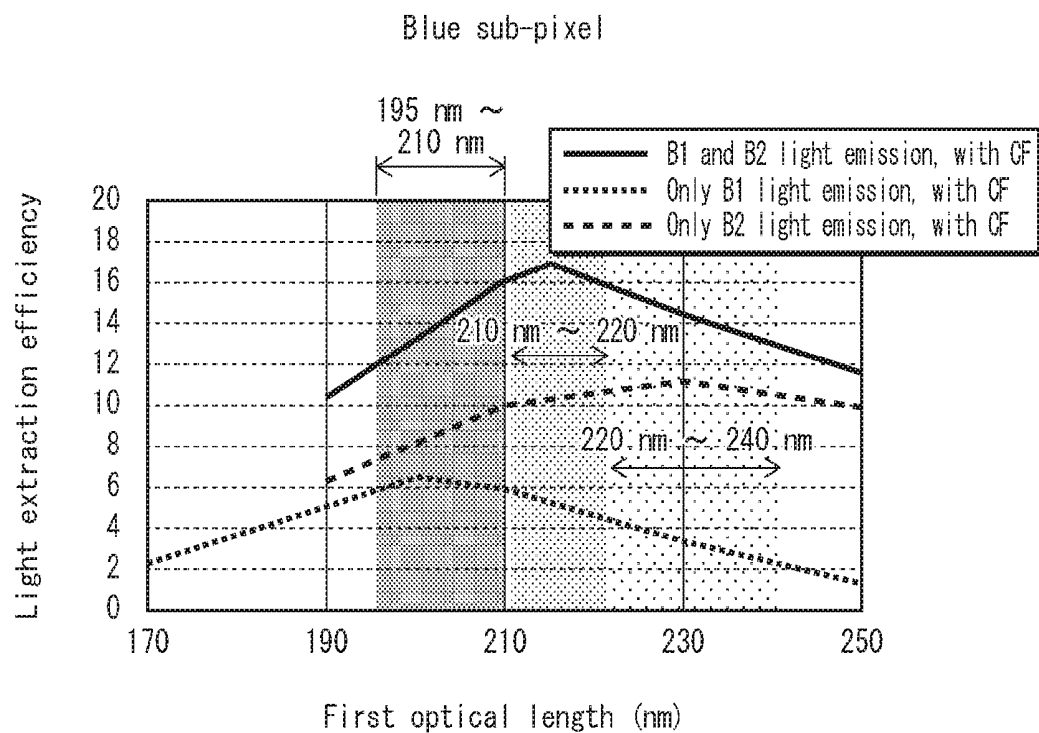
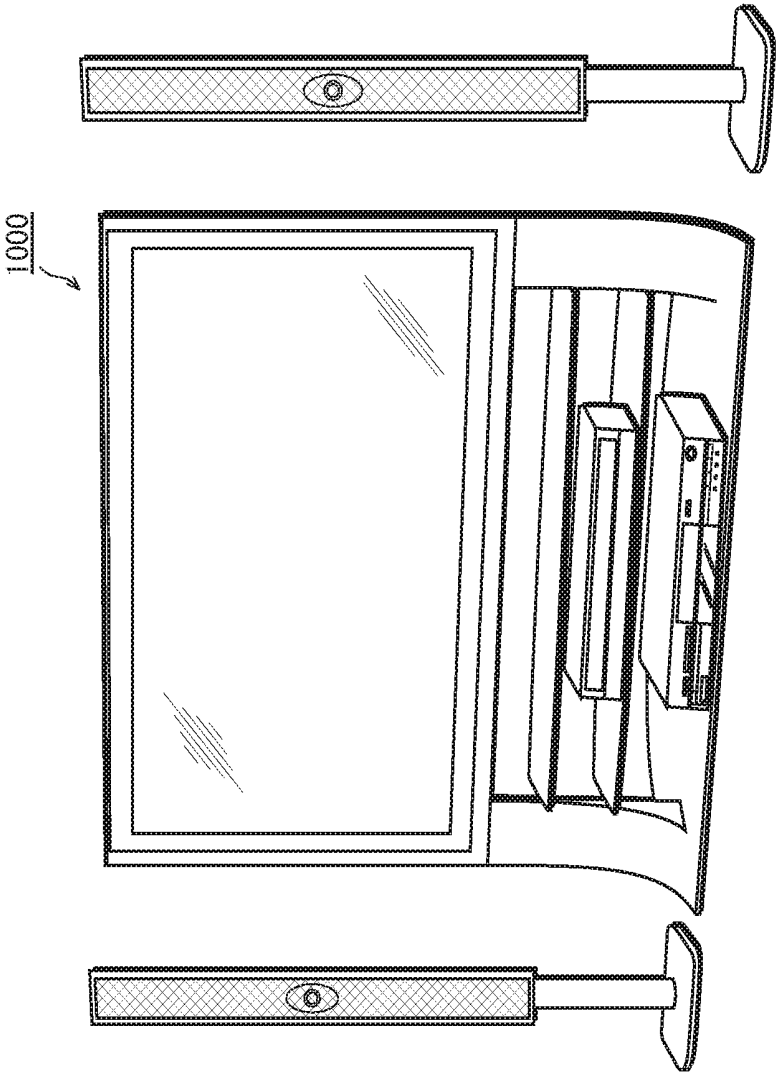


FIG. 15



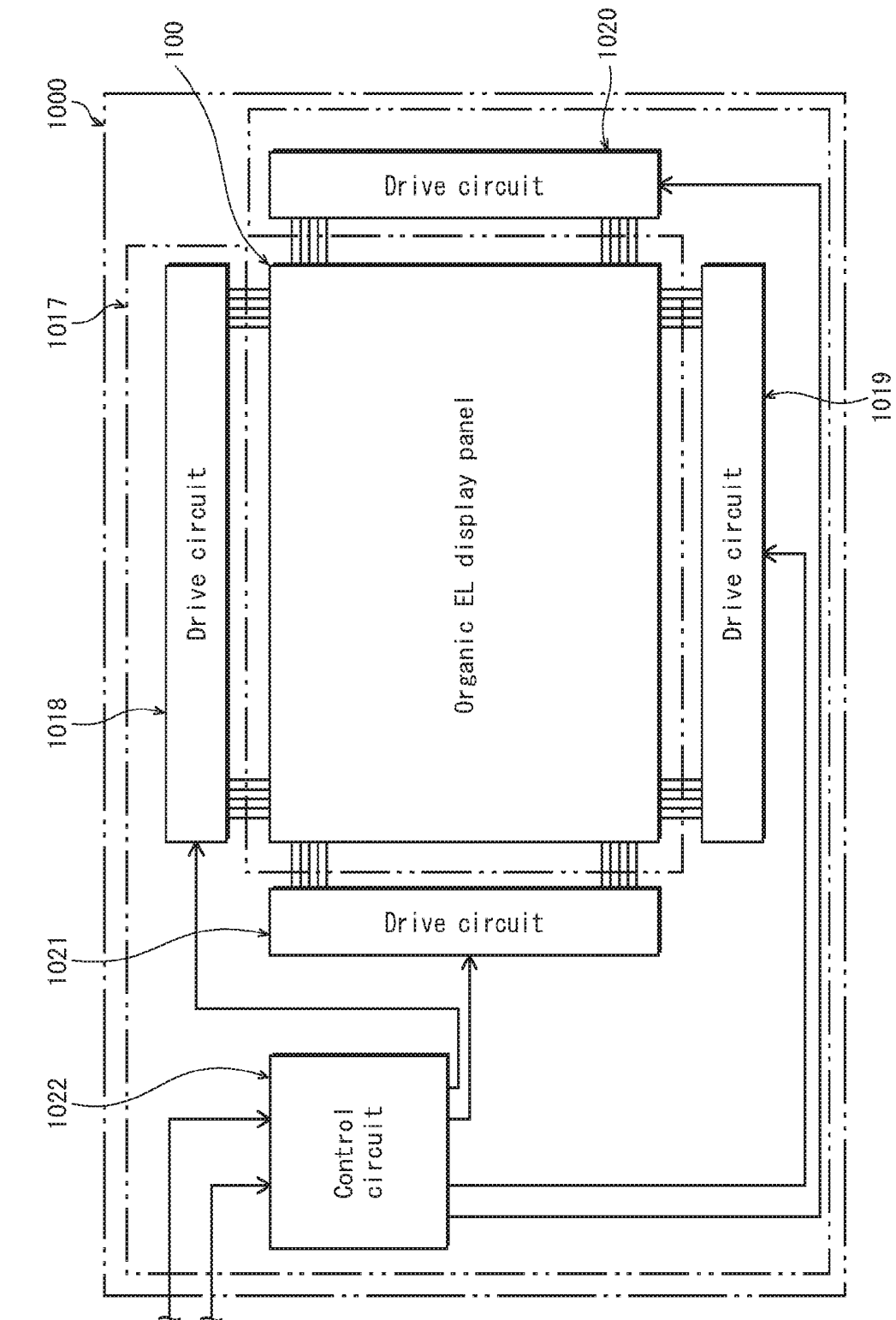


FIG. 16

**ORGANIC EL DISPLAY PANEL WITH
SECOND BLUE EMITTER, DISPLAY
DEVICE PROVIDED THEREWITH, AND
METHOD FOR MANUFACTURING
ORGANIC EL DISPLAY PANEL**

TECHNICAL FIELD

The present disclosure relates to organic electroluminescence (EL) display panels incorporating tandem-structure organic EL elements, display devices incorporating organic EL display panels, and organic EL display panel manufacturing methods.

BACKGROUND ART

In recent years, as display panels used in display devices such as digital televisions, organic electroluminescence (EL) display panels that use electroluminescence of organic materials are being implemented in which a plurality of organic EL elements are arrayed on a substrate.

As an organic EL display panel configuration, typically thin film transistor (TFT) drive circuitry is disposed on a substrate, an insulating layer is disposed on the TFT drive circuitry, and a plurality of organic EL elements are arrayed thereon. An organic EL element has, at minimum, a light-emitting layer sandwiched between a pair of electrodes (anode and cathode). Typically, an organic EL element has a hole injection layer and a hole transport layer between the anode and the light-emitting layer, and an electron injection layer and an electron transport layer between the cathode and the light-emitting layer. The hole injection layer, the hole transport layer, the electron injection layer, and the electron transport layer fulfil their respective specific functions of charge injection, charge transport, etc. In the present disclosure, such layers are referred to collectively as "functional layers". Such an organic EL element is a current-driven light-emitting element. When driven, a voltage is applied between the anode and the cathode, and light is emitted when holes and electrons injected into the light-emitting layer recombine.

In an organic EL display panel, such organic EL elements form sub-pixels in red, green, and blue colors, combinations of adjacent red, green, and blue sub-pixels forming pixels. In such an organic EL display panel, in order to reduce energy consumption and increase longevity, improving light emission efficiency and longevity of the organic EL elements for each of red, green, and blue colors are important. Among red, green, and blue colors of organic EL elements, lifespan of blue organic EL elements tends to be shortest, and therefore increasing longevity of blue organic EL elements is a technical problem for increasing longevity of display devices.

Patent Literature 1, 2, and 3 disclose implementing increased organic EL element longevity by adoption of an organic EL element structure in which a plurality of light-emitting units that include a light-emitting layer (a light-emitting unit being equivalent to a conventional organic light-emitting element without anode and cathode elements) are stacked (this may be referred to as a multiphoton structure, tandem structure, or stack structure, but this disclosure refers to a tandem structure). A tandem structure is a structure in which light-emitting units are stacked on both sides of a charge generating layer (a portion thereof in contact with a light-emitting unit may be referred to as a charge generating layer, an intermediate layer, an intermediate conductive layer, a connector, etc., but this disclosure

refers to a charge generating layer). This charge generating layer supplies charge to the light-emitting units above and below it, and therefore light can be emitted from a plurality of light-emitting units in a tandem structure. As a result, light emitted from an organic EL element that has a tandem structure is a sum of light emitted from a plurality of light-emitting units, and therefore current required to obtain a desired luminance is decreased, and longevity of the current-driven type of organic EL element can be increased.

In order to adapt a tandem structure to an organic EL display panel, which light emission colors of light-emitting units to layer and how to layer them in red, green, and blue sub-pixels become important.

Resistance heating, coating application, printing, etc., are methods of film formation for light-emitting layers and functional layers made from organic light-emitting material. When vacuum deposition is used for film formation of light-emitting layers or functional layers of different sub-pixels, a precision shadow mask is typically used that is only open at sub-pixel regions. In such a case, material that forms light-emitting layers or functional layers attaches to portions of the shadow mask other than the openings, and this loss of material is a cause of increased manufacturing cost. Further, accurate alignment of openings of the precision shadow mask to sub-pixels is a factor lowering production efficiency, and in particular when producing large organic EL display panels the alignment of shadow mask to sub-pixels is very difficult.

Thus, from the perspectives of manufacturing costs and enlargement of an organic EL display panel, research is being actively pursued into film formation in which a low-molecular or high-molecular organic material is dissolved in solution or dispersed, and a light-emitting layer and functional layer including organic light-emitting material are formed by a wet process. However, there is a problem in that an organic EL element formed by using a wet process has a shorter lifespan than an organic EL element formed by using vacuum deposition.

Patent Literature 4 discloses a tandem structure in which blue light-emitting units are layered only in blue sub-pixels, in an organic EL display panel, by using a combination of wet and vacuum deposition processes. As a result, longevity and productivity of blue organic EL elements are improved, and manufacturing cost is decreased. More specifically, after forming a first red light-emitting unit including a red light-emitting layer, a first green light-emitting unit including a green light-emitting layer, and a first blue light-emitting unit including a first blue light-emitting layer by using wet processes, a charge generating layer is formed only in a blue sub-pixel region by using a vacuum deposition process. Subsequently, a second blue light-emitting unit including a second blue light-emitting layer is formed by using vacuum deposition so as to cover the first red light-emitting unit in a red sub-pixel, the first green light-emitting unit in a green sub-pixel, and the charge generating layer in the blue sub-pixel. Thus, there is no charge generating layer between the first red light-emitting unit and the second blue light-emitting unit, and the second blue light-emitting unit only has an electron transport function, and therefore light is not emitted from the second blue light-emitting unit in the red sub-pixel. The same is true for the green sub-pixel. According to this configuration, Patent Literature 4 discloses that longevity can be increased, manufacturing cost decreased, and productivity improved for a blue organic EL element.

CITATION LIST

Patent Literature

[Patent Literature 1] JP 3884565
 [Patent Literature 2] JP 4570014
 [Patent Literature 3] JP 3933591
 [Patent Literature 4] JP 2013-73759

SUMMARY OF INVENTION

Technical Problem

However, use of a precision shadow mask is required to form a charge generating layer in only a blue sub-pixel, and a further improvement in productivity is desired. Furthermore, in red and green sub-pixels, the second blue light-emitting units only function for electron transport despite having light-emitting functionality, and an increase in drive voltage for the red and green organic EL elements is also a concern.

The technology pertaining to the present disclosure is achieved in view of the above circumstances, and aims to provide an organic EL display panel in which longevity of blue organic EL elements is improved, and which excels in terms of manufacturing cost and productivity, a display device that uses the organic EL display panel, and a method of manufacturing the organic EL display panel.

Solution to Problem

An organic EL display pertaining to one aspect of the present disclosure is an organic EL display panel comprising: a substrate; a plurality of banks, disposed above the substrate, that define a red sub-pixel region, a green sub-pixel region, and a blue sub-pixel region; a plurality of light-reflective electrodes, disposed above the substrate in the red sub-pixel region, the green sub-pixel region, and the blue sub-pixel region, each of the light-reflective electrodes having a light-reflective surface; a first red light-emitting unit disposed above a first one of the light-reflective electrodes in the red sub-pixel region, the first red light-emitting unit including a red light-emitting layer comprising a material that has an emission peak in a red wavelength band, the red light-emitting layer having a light-emitting surface that faces the light-reflective surface of the first one of the light-reflective electrodes; a first green light-emitting unit disposed above a second one of the light-reflective electrodes in the green sub-pixel region, the first green light-emitting unit including a green light-emitting layer comprising a material that has an emission peak in a green wavelength band, the green light-emitting layer having a light-emitting surface that faces the light-reflective surface of the second one of the light-reflective electrodes; a first blue light-emitting unit disposed above a third one of the light-reflective electrodes in the blue sub-pixel region, the first blue light-emitting unit including a first blue light-emitting layer comprising a material that has an emission peak in a blue wavelength band, the first blue light-emitting layer having a light-emitting surface that faces the light-reflective surface of the third one of the light-reflective electrodes; a charge generating layer disposed above the first red light-emitting unit, the first green light-emitting unit, and the first blue light-emitting unit in the red sub-pixel region, the green sub-pixel region, and the blue sub-pixel region; a second blue light-emitting unit disposed above the charge generating layer in the red sub-pixel region, the green

sub-pixel region, and the blue sub-pixel region, the second blue light-emitting unit including a second blue light-emitting layer comprising a material that has an emission peak in a blue wavelength band, the second blue light-emitting layer having light-emitting surfaces that each face corresponding ones of the light-reflective surfaces of the light-reflective electrodes; and a light-transmissive electrode disposed above the second blue light-emitting unit in the red, the green and the blue sub-pixel regions. In the red sub-pixel region, an optical length between the light-emitting surface of the red light-emitting layer and the light-reflective surface of the first one of the light-reflective electrodes is from 20 nm to 50 nm. In the green sub-pixel region, an optical length between the light-emitting surface of the green light-emitting layer and the light-reflective surface of the second one of the light-reflective electrodes is from 20 nm to 50 nm. In the blue sub-pixel region, an optical length between the light-emitting surface of the first blue light-emitting layer and the light-reflective surface of the third one of the light-reflective electrodes is from 20 nm to 60 nm. In the red sub-pixel region, an optical length between one of the light-emitting surfaces of the second blue light-emitting layer and the light-reflective surface of the first one of the light-reflective electrodes is from 210 nm to 230 nm. In the green sub-pixel region, an optical length between one of the light-emitting surfaces of the second blue light-emitting layer and the light-reflective surface of the second one of the light-reflective electrodes is from 240 nm to 295 nm. In the blue sub-pixel region, an optical length between one of the light-emitting surfaces of the first blue light-emitting layer and the light-reflective surface of the third one of the light-reflective electrodes is from 195 nm to 205 nm.

Advantageous Effects of the Invention

According to the organic EL display panel pertaining to one aspect of the present disclosure, the charge generating layer is present in the red sub-pixel region, the green sub-pixel region, and the blue sub-pixel region. Thus, the charge generating layer can be formed without using a precise shadow mask. Accordingly, manufacturing cost and productivity improvements can be made.

Further, optical lengths in the blue sub-pixel region are within the ranges stated above, and therefore blue light emitted from both the first blue light-emitting layer and the second blue light-emitting layer can be efficiently extracted. Accordingly, current required to obtain a desired luminance is decreased, and therefore lifespan of current-driven organic EL elements can be increased.

Further, optical lengths in the red sub-pixel region are within the ranges stated above, and therefore light extraction efficiency of red light emitted from the red light-emitting layer in the red sub-pixel region is improved, while suppressing light extraction efficiency of blue light emitted from the second blue light-emitting layer. In the red sub-pixel region, light extraction efficiency of unwanted blue light is suppressed, and therefore a decrease in red color purity is suppressed.

Further, optical lengths in the green sub-pixel region are within the ranges stated above, and therefore light extraction efficiency of green light emitted from the green light-emitting layer in the green sub-pixel region is improved, while suppressing light extraction efficiency of blue light emitted from the second blue light-emitting layer. In the green sub-pixel region, light extraction efficiency of

unwanted blue light is suppressed, and therefore a decrease in green color purity is suppressed.

BRIEF DESCRIPTION OF DRAWINGS

FIG. 1 is a cross-section enlargement of a pixel of an organic EL display panel pertaining to Embodiment 1.

FIG. 2 illustrates light paths of light emitted from organic EL elements pertaining to Embodiment 1.

FIG. 3A, FIG. 3B, and FIG. 3C illustrate changes in light extraction efficiency and chromaticity of light emitted from an organic EL element with respect to first optical lengths.

FIG. 4A, FIG. 4B, and FIG. 4C illustrate changes in light extraction efficiency and chromaticity of light emitted from an organic EL element with respect to second optical lengths.

FIG. 5 illustrates a more detailed simulation with respect to red sub-pixels.

FIG. 6 illustrates a more detailed simulation with respect to blue sub-pixels.

FIG. 7A, FIG. 7B, FIG. 7C, FIG. 7D, and FIG. 7E illustrate an organic EL display panel manufacturing method pertaining to Embodiment 1.

FIG. 8 is a cross-section enlargement of a pixel of an organic EL display panel pertaining to Embodiment 2.

FIG. 9 illustrates light paths of light emitted from organic EL elements pertaining to Embodiment 2.

FIG. 10 illustrates changes in light extraction efficiency and chromaticity of light emitted from an organic EL element with respect to second optical lengths.

FIG. 11A, FIG. 11B, and FIG. 11C illustrate changes in light extraction efficiency and chromaticity of light emitted from an organic EL element with respect to first optical lengths.

FIG. 12A illustrates a light emission spectrum when the first optical length is 210 nm, and FIG. 12B illustrates a light emission spectrum when the first optical length is 290 nm.

FIG. 13 illustrates a more detailed simulation with respect to red sub-pixels.

FIG. 14 illustrates a more detailed simulation with respect to blue sub-pixels.

FIG. 15 is an external view of a display device.

FIG. 16 is a block diagram illustrating internal elements of the display device.

EMBODIMENTS

The following illustrates specific examples, and describes configurations, operations, and effects related thereto.

The embodiments described below are illustrative examples used to better describe configurations, operations, and effects of an aspect of the present invention, and aside from essential elements thereof, the present invention is not limited to the following examples.

Embodiments

[1. Configuration of Organic EL Display Panel (Top-Emission)]

A configuration of an organic EL display panel pertaining to Embodiment 1 of the present disclosure is described below, with reference to FIG. 1. FIG. 1 is a cross-section enlargement of a pixel of an organic EL display panel pertaining to Embodiment 1 of the present disclosure. According to the present embodiment, an organic EL display panel 100 is a so-called "top-emission" type, in which a display surface thereof is towards the upper side of FIG. 1.

The organic EL display panel 100 includes a first substrate 1, banks 2, an insulating layer 3, light-reflective electrodes 4, first hole injection layers 5, first hole transport layers 6, a red light-emitting layer 7R, a green light-emitting layer 7G, a blue light-emitting layer 7B, a first electron transport layer 8, a charge generating layer 9, a second hole transport layer 10, a second blue light-emitting layer 11, a second electron transport layer 12, a light-transmissive electrode 13, a protective layer 14, a color filter layer 15, and a second substrate 16.

The first substrate 1 is, for example, a TFT substrate including an electrically-insulative base material and a TFT layer disposed on the base material. The TFT layer includes a plurality of TFT drive circuits, and a plurality of wires that supply external power to the TFT drive circuits.

The insulating layer 3 is disposed on the first substrate 1. An upper surface of the insulating layer 3 is planarized.

The banks 2 are disposed on the insulating layer 3, separated from each other. The banks 2 define a red sub-pixel region 2R, a green sub-pixel region 2G, and a blue sub-pixel region 2B.

The light-reflective electrodes 4 are disposed on the insulating layer 3, separated from each other. The insulating layer 3 has a plurality of contact holes (not illustrated). Wiring is buried in each of the contact holes (not illustrated). Each of the light-reflective electrodes 4 is electrically connected to a corresponding one of the TFT drive circuits in the first substrate 1 via wiring buried in a corresponding one of the contact holes. According to the present embodiment, the light-reflective electrodes 4 function as anodes supplying holes to the first hole injection layers 5.

In the red sub-pixel region 2R, one of the first hole injection layers 5, one of the first hole transport layers 6, and the red light-emitting layer 7R are layered in this order on one of the light-reflective electrodes 4. In the green sub-pixel region 2G, one of the first hole injection layers 5, one of the first hole transport layers 6, and the green light-emitting layer 7G are layered in this order on one of the light-reflective electrodes 4. In the blue sub-pixel region 2B, one of the first hole injection layers 5, one of the first hole transport layers 6, and the first blue light-emitting layer 7B are layered in this order on one of the light-reflective electrodes 4. Hereinafter, when the red light-emitting layer 7R, the green light-emitting layer 7G, and the first blue light-emitting layer 7B are not differentiated, they are referred to as "first light-emitting layers 7".

The first hole injection layers 5 have a function of promoting injection of holes from the light-reflective electrodes 4 to the first hole transport layers 6 and the first light-emitting layers 7. The first hole injection layers 5 in the sub-pixel regions may be separated from each other by the banks 2, or may be connected to each other across the banks 2. When separated by the banks 2, the first hole injection layers 5 may be the same thickness as each other or different thicknesses from each other, and the first hole injection layers 5 may be the same material as each other or different materials from each other. When connected to each other across the banks 2, the first hole injection layers 5 may be connected across bottom surfaces of the banks 2 by being formed before the banks 2 are formed, or may be connected across top surfaces of the banks 2 by being formed after the banks 2 are formed.

The first hole transport layers 6 have functions of promoting hole injection from the first hole injection layers 5 to the first light-emitting layers 7 and blocking escape of electrons and exciton energy from the first light-emitting layers 7. The first hole transport layers 6 in the sub-pixel

regions may be separated from each other by the banks 2, or may be connected to each other across the banks 2. When separated by the banks 2, the first hole transport layers 6 may be the same thickness as each other or different thicknesses from each other, and the first hole transport layers 6 may be the same material as each other or different materials from each other. When connected to each other across the banks 2, the first hole transport layers 6 may be connected across bottom surfaces of the banks 2 by being formed before the banks 2 are formed, or may be connected across top surfaces of the banks 2 by being formed after the banks 2 are formed. The first hole injection layers 5 and the first hole transport layers 6 may be formed as a single layer, and additional layers may be added.

The first light-emitting layers 7 have a function of emitting light according to recombination of holes and electrons. The red light-emitting layer 7R, the green light-emitting layer 7G, and the first blue light-emitting layer 7B are separated from each other by the banks 2. The red light-emitting layer 7R includes a material that has a light emission peak in a red wavelength band. The green light-emitting layer 7G includes a material that has a light emission peak in a green wavelength band. The first blue light-emitting layer 7B includes a material that has a light emission peak in a blue wavelength band. The red light-emitting layer 7R, the green light-emitting layer 7G, and the first blue light-emitting layer 7B may have the same thickness as each other or may have different thicknesses to each other.

The first electron transport layer 8 includes portions disposed on the first light-emitting layers 7 in the red sub-pixel region 2R, the green sub-pixel region 2G, and the blue sub-pixel region 2B. The portions are connected to each other over the banks 2. The first electron transport layer 8 has a function of transporting electrons supplied from the charge generating layer 9 to the first light-emitting layers 7. The first electron transport layer 8 may be formed from a plurality of layers.

The charge generating layer 9 includes portions disposed on the first electron transport layer 8 in the red sub-pixel region 2R, the green sub-pixel region 2G, and the blue sub-pixel region 2B. The portions are connected to each other over the banks 2. The charge generating layer 9 has functions of supplying electrons to the first electron transport layer 8 and supplying holes to the second hole transport layer 10. The charge generating layer 9 may be formed from a plurality of layers.

In the red sub-pixel region 2R, the green sub-pixel region 2G, and the blue sub-pixel region 2B, the second hole transport layer 10, the second blue light-emitting layer 11, and the second electron transport layer 12 are layered on the charge generating layer 9 in this order. The second hole transport layer 10 has functions of transporting holes supplied from the charge generating layer 9 to the second blue light-emitting layer 11 and of blocking escape of electrons and exciton energy from the second blue light-emitting layer 11. The second blue light-emitting layer 11 has a function of emitting light according to recombination of holes and electrons. The second blue light-emitting layer 11 includes a material that has a light emission peak in a blue wavelength band. The second electron transport layer 12 has a function of transporting electrons supplied from the light-transmissive electrode 13 to the second blue light-emitting layer 11. The second hole transport layer 10 and the second electron transport layer 12 may be formed from a plurality of layers.

The light-transmissive electrode 13 includes portions disposed on the second electron transport layer 12 in the red

sub-pixel region 2R, the green sub-pixel region 2G, and the blue sub-pixel region 2B. The portions are connected to each other over the banks 2. According to the present embodiment, the light-transmissive electrode 13 functions as a cathode supplying electrons to the second electron transport layer 12. The light-transmissive electrode 13 may be formed from a plurality of layers.

The protective layer 14 is disposed on the light-transmissive electrode 13. The protective layer 14 has a function of protecting the layers, from the light-reflective electrodes 4 to the light-transmissive electrode 13, from moisture and oxygen.

The color filter layer 15 is disposed on the protective layer 14. The color filter layer 15 includes a red filter 15R, a green filter 15G, and a blue filter 15B. The red filter 15R is positioned above the red sub-pixel region 2R. The green filter 15G is positioned above the green sub-pixel region 2G. The blue filter 15B is positioned above the blue sub-pixel region 2B. The color filter layer 15 has a function of correcting chromaticity of emitted light.

The second substrate 16 is disposed on the color filter layer 15.

A first red light-emitting unit 17R comprises one of the first hole injection layers 5, one of the first hole transport layers 6, the red light-emitting layer 7R, and the first electron transport layer 8, all in the red sub-pixel region 2R. A first green light-emitting unit 17G comprises one of the first hole injection layers 5, one of the first hole transport layers 6, the green light-emitting layer 7G, and the first electron transport layer 8, all in the green sub-pixel region 2G. A first blue light-emitting unit 17B comprises one of the first hole injection layers 5, one of the first hole transport layers 6, the first blue light-emitting layer 7B, and the first electron transport layer 8, all in the blue sub-pixel region 2B.

A second blue light-emitting unit 18B comprises the second hole transport layer 10, the second blue light-emitting layer 11, and the second electron transport layer 12, in the red sub-pixel region 2R, the green sub-pixel region 2G, and the blue sub-pixel region 2B.

As above, in the red sub-pixel region 2R, the charge generating layer 9 is layered between the first red light-emitting unit 17R and the second blue light-emitting unit 18B. In the green sub-pixel region 2G, the charge generating layer 9 is layered between the first green light-emitting unit 17G and the second blue light-emitting unit 18B. In the blue sub-pixel region 2B, the charge generating layer 9 is layered between the first blue light-emitting unit 17B and the second blue light-emitting unit 18B. Accordingly, it can be said that tandem-type organic EL elements are in the red sub-pixel region 2R, the green sub-pixel region 2G, and the blue sub-pixel region 2B.

[2. Optical Design (Top-Emission)]

According to the present embodiment, the charge generating layer 9 and the second blue light-emitting layer 11 are disposed in the red sub-pixel region 2R, the green sub-pixel region 2G, and the blue sub-pixel region 2B. Thus, not only the organic EL element in the blue sub-pixel region 2B, but also the organic EL elements in the red sub-pixel region 2R and the in the green sub-pixel region 2G emit blue light. However, for example, for the organic EL element in the red sub-pixel region, blue light is unnecessary; if blue light were emitted externally unaltered, chromaticity of light emitted from the red sub-pixel region 2R would be adversely affected. Thus, on a side of the organic EL element from which light is emitted, a red filter is preferably provided that changes chromaticity of emitted light to red.

However, in order to increase light extraction efficiency (ratio of light emitted internally to light outputted), it is necessary to reduce an amount of light absorbed by the red filter, from light emitted by the organic EL element in the red sub-pixel region. Conventionally, a known technique for improving light extraction efficiency of an organic EL element is appropriately designing thickness and refractive index of each layer of the organic EL element, appropriately adjusting microcavity structures of the organic EL element. Typically, light extraction efficiency is improved for one of red light, green light, and blue light, or for two or more colors of emitted light intended to produce white light.

According to the structure of the organic EL elements of the present embodiment, the second blue light-emitting layer 11 in the red sub-pixel region 2R, the green sub-pixel region 2G, and the blue sub-pixel region 2B emits blue light. Thus, in the blue sub-pixel region 2B, it is preferable to increase light extraction efficiency for both blue light emitted by the first blue light-emitting layer 7B and blue light emitted by the second blue light-emitting layer 11. In contrast, in the green sub-pixel region 2G, it is preferable to increase light extraction efficiency for green light emitted by the green light-emitting layer 7G and decrease light extraction efficiency for blue light emitted by the second blue light-emitting layer 11. In the red sub-pixel region 2R, it is preferable to increase light extraction efficiency for red light emitted by the red light-emitting layer 7R and decrease light extraction efficiency for blue light emitted by the second blue light-emitting layer 11. In other words, because desired chromaticity of emitted light is different for each sub-pixel, a design is required that controls light extraction efficiency appropriately for the organic EL elements the red sub-pixel region 2R, the green sub-pixel region 2G, and the blue sub-pixel region 2B. In particular, a design is required, for the organic EL elements in the red sub-pixel region 2R and the green sub-pixel region 2G, that can simultaneously improve light extraction efficiency and decrease light extraction efficiency.

FIG. 2 illustrates optical paths of light emitted from the organic EL elements in sub-pixel regions.

An optical path C1a is an optical path of light travelling from one of the first light-emitting layers 7, towards the light-transmissive electrode 13, without travelling towards the light-reflective electrodes 4. An optical path C1b is an optical path of light travelling from one of the first light-emitting layers 7 towards the light-reflective electrodes 4, being reflected at one of the light-reflective electrodes 4, and subsequently travelling towards the light-transmissive electrode 13. An optical path C2a is an optical path of light travelling from the second blue light-emitting layer 11, towards the light-transmissive electrode 13, without travelling towards the light-reflective electrodes 4. An optical path C2b is an optical path of light travelling from the second blue light-emitting layer 11 towards the light-reflective electrodes 4, being reflected at one of the light-reflective electrodes 4, and subsequently travelling towards the light-transmissive electrode 13.

As stated above, the first hole transport layers 6 have the function of blocking escape of electrons from the first light-emitting layers 7. Thus, electrons in the first light-emitting layers 7 tend to accumulate in the vicinity of interfaces between the first light-emitting layers 7 and the first hole transport layers 6 (bottom surfaces of the first light-emitting layers 7). Recombination of electrons and holes tends to occur in the vicinity of the bottom surfaces of the first light-emitting layers 7, and therefore light emission intensity is greater in the vicinity of the bottom surfaces of

the first light-emitting layers 7. According to the present embodiment, the bottom surfaces of the first light-emitting layers 7 are referred to as light-emitting surfaces 7a of the first light-emitting layers 7. Similarly, a bottom surface of the second blue light-emitting layer 11 is referred to as a light-emitting surface 11a of the second blue light-emitting layer 11. When designing microcavity structure of an organic EL element, it is sufficient to consider optical lengths L1R, L1G, L1B (hereinafter, "first optical lengths") between the light-emitting surfaces 7a of the first light-emitting layers 7 and light reflecting surfaces 4a of the light-reflective electrodes 4 and optical lengths L2R, L2G, L2B (hereinafter, "second optical lengths") between the light-emitting surface 11a of the second blue light-emitting layer 11 and the light reflecting surfaces 4a of the light-reflective electrodes 4.

According to the present embodiment, the bottom surfaces of the first light-emitting layers 7 are light-emitting surfaces of the first light-emitting layers 7, but this is just an example. As another example, as long as the first electron transport layer 8 has a function of blocking the escape of holes from the first light-emitting layers 7 in addition to the function of injecting electrons into the first light-emitting layers 7, upper surfaces of the first light-emitting layers 7 may be light-emitting surfaces of the first light-emitting layers 7. This also applies to the second blue light-emitting layer 11.

[3. First Optical Lengths (Top-Emission)]

FIG. 3A, FIG. 3B, and FIG. 3C show optical simulation results, and indicate changes in light extraction efficiency and chromaticity of organic EL elements with respect to first optical lengths. FIG. 3A indicates a red sub-pixel, FIG. 3B indicates a green sub-pixel, and FIG. 3C indicates a blue sub-pixel. Here, y values are values in CIE chromaticity coordinates. Typically, optical length is a physical amount equal to the product of film thickness of layers and their refractive indices, but according to the present embodiment, optical length is indicated as film thickness of layers. Light extraction efficiency indicates a value prior to light absorption by the color filter layer, i.e., a value of light emitted from a first light-emitting layer. Base values for film thickness of each layer were set as follows:

Light-reflective electrode: 200 nm (silver alloy)

First hole injection layer: 20 nm (electrically conductive polymer material)

First hole transport layer: 10 nm (amine compound)

First light-emitting layer: 50 nm (polyfluorene derivative)

First electron transport layer: 35 nm (phenanthroline derivative)

Charge generating layer: 10 nm (HAT-CN6)

Second hole transport layer: 30 nm (amine compound)

Second blue light-emitting layer: 25 nm (anthracene compound)

Second electron transport layer: 35 nm (phenanthroline derivative)

Light transmissive electrode: 35 nm (ITO)

Refractive indices of the materials were evaluated by spectroscopic ellipsometry.

According to the present embodiment, first optical lengths are represented by the sum of film thicknesses of the first hole injection layer and the first hole transport layer. FIG. 3A, FIG. 3B, and FIG. 3C show cases in which film thicknesses of the first hole injection layers are varied (dashed lines) and cases in which film thicknesses of the first hole transport layers are varied (solid lines). Because both materials are organic materials, they have substantially the same refractive indices. Thus, it can be seen that changes in

either film thickness shows the same trends. In other words, film thickness of any layer between the light reflecting surfaces of light-reflective electrodes and light-emitting surfaces of the first light-emitting layers may be adjusted, and a layer such as a hole injection layer and a hole transport layer may be added.

In FIG. 3A, the organic EL element in the red sub-pixel region has a peak light extraction efficiency when the first optical length is approximately 30 nm. When the first optical length is equal to or less than 50 nm, peak values of light extraction efficiency equal to or greater than 90% can be ensured. In order to express the functions of hole injection and hole transport of the first hole injection layer and the first hole transport layer, the first optical length is preferably equal to or greater than 20 nm. Accordingly, the organic EL element in the red sub-pixel region preferably has the first optical length set from 20 nm to 50 nm.

In FIG. 3B, the organic EL element in the green sub-pixel region has a peak light extraction efficiency when the first optical length is approximately 10 nm. When the first optical length is equal to or less than 50 nm, peak values of light extraction efficiency equal to or greater than 90% can be ensured. For the same reasons as with the red sub-pixel region, the first optical length is preferably equal to or greater than 20 nm. Accordingly, the organic EL element in the green sub-pixel region preferably has the first optical length set from 20 nm to 50 nm.

In FIG. 3C, the organic EL element in the blue sub-pixel region has a peak light extraction efficiency when the first optical length is approximately 40 nm. When the first optical length is equal to or less than 60 nm, peak values of light extraction efficiency equal to or greater than 90% can be ensured. For the same reasons as with the red sub-pixel region, the first optical length is preferably equal to or greater than 20 nm. Accordingly, the organic EL element in the blue sub-pixel region preferably has the first optical length set from 20 nm to 60 nm.

[4. Second Optical Lengths (Top-Emission)]

FIG. 4A, FIG. 4B, and FIG. 4C show optical simulation results, and indicate changes in light extraction efficiency and chromaticity of organic EL elements with respect to second optical lengths. FIG. 4A indicates a red sub-pixel, FIG. 4B indicates a green sub-pixel, and FIG. 4C indicates a blue sub-pixel. Light extraction efficiency indicates a value prior to light absorption by the color filter layer, i.e., a value with respect to the sum of light emitted from a first light-emitting layer and light emitted from the second blue light-emitting layer. Base values for film thickness of each layer were set as follows:

Light-reflective electrode: 200 nm (silver alloy)
First hole injection layer: 20 nm (electrically conductive polymer material)

First hole transport layer: 10 nm (amine compound)

First light-emitting layer: 50 nm (polyfluorene derivative)

First electron transport layer: 35 nm (phenanthroline derivative)

Charge generating layer: 10 nm (HAT-CN6)

Second hole transport layer: 30 nm (amine compound)

Second blue light-emitting layer: 25 nm (anthracene compound)

Second electron transport layer: 35 nm (phenanthroline derivative)

Light transmissive electrode: 35 nm (ITO)

Refractive indices of the materials were evaluated by spectroscopic ellipsometry.

According to the present embodiment, the second optical lengths are represented by the sum of film thicknesses of the

first hole injection layer, the first hole transport layer, the first light-emitting layer, the first electron transport layer, the charge generating layer, and the second hole transport layer. FIG. 4A, FIG. 4B, and FIG. 4C show cases in which film thicknesses of the second hole transport layer are changed.

In FIG. 4A, the organic EL element in the red sub-pixel region has a peak light extraction efficiency when the second optical length is approximately 195 nm. When the second optical length is from 160 nm to 230 nm, peak values of light extraction efficiency equal to or greater than 90% can be ensured. Note that results around 160 nm are not shown in FIG. 4A. On the other hand, when the second optical length is from 210 nm to 265 nm, a y value in an appropriate range for the red sub-pixel (equal to or greater than 0.30) can be ensured. Accordingly, the organic EL element in the red sub-pixel region preferably has the second optical length set from 210 nm to 230 nm. Thus, chromaticity of emitted light in an appropriate range can be ensured while increasing light extraction efficiency.

FIG. 5 shows results of a more detailed simulation with respect to red sub-pixels. The upper graph in FIG. 5 shows changes in light extraction efficiency, and the lower graph in FIG. 5 shows changes in chromaticity. When color correction using the color filter layer is implemented (solid line), light extraction efficiency peaks when the second optical length is approximately 220 nm. When the second optical length is from 210 nm to 230 nm, a high light extraction efficiency can be maintained when color correction is implemented using a color filter. Further, from the results of FIG. 4A and FIG. 5, it can be seen that light extraction efficiency peaks when the second optical length is 195 nm when color correction is not implemented, but does not peak when the second optical length is 195 nm when color correction is implemented. Thus, the proportion of unwanted blue light seems relatively large when the second optical length is approximately 195 nm.

Further, the organic EL element in the red sub-pixel region includes the red light-emitting layer and the second blue light-emitting layer. When optimizing the second optical length, the red light-emitting layer and the second blue light-emitting layer may be considered separately. In the present device it is not possible for only the second blue light-emitting layer to emit light without the red light-emitting layer emitting light, but in a simulation such a condition can be reproduced. Accordingly, the condition of only the second blue light-emitting layer emitting light can be reproduced in a simulation, and the second optical length that produces the minimum light extraction efficiency can be sought. However, even if the red light-emitting layer and the second blue light-emitting layer are separately optimized, it has been found that it is not always possible to optimize both light extraction efficiency and chromaticity. The dashed line in the graph of the upper half of FIG. 5 indicates light extraction efficiency when only the second blue light-emitting layer emits light and the red light-emitting layer does not emit light. According to this simulation, for example, light extraction efficiency is low when the second optical length is in a range from 170 nm to 180 nm. In other words, when optimizing for only the second blue light-emitting layer, it is likely that the second optical length in the range from 170 nm to 180 nm would be selected. However, as stated above, a preferable range for the second optical length of the organic EL element in the red sub-pixel region is not in the range from 170 nm to 180 nm, and is in the range from 210 nm to 230 nm. Accordingly, when optimizing the second optical length, it is important to consider both the red light-emitting layer and the second blue light-emitting layer

at the same time, not separately. According to the present embodiment, the red light-emitting layer and the second blue light-emitting layer are both considered at the same time, and therefore a range for the second optical length that optimizes both light extraction efficiency and chromaticity can be obtained.

In FIG. 4B, the organic EL element in the green sub-pixel region has a peak light extraction efficiency when the second optical length is approximately 270 nm. When the second optical length is from 240 nm to 300 nm, peak values of light extraction efficiency equal to or greater than 90% can be ensured. On the other hand, when the second optical length is from 210 nm to 295 nm, a y value in an appropriate range for the green sub-pixel (equal to or greater than 0.50) can be ensured. Note that results around 210 nm are not shown in FIG. 4B. Accordingly, the organic EL element in the green sub-pixel region preferably has the second optical length set from 240 nm to 295 nm. Thus, chromaticity of emitted light in an appropriate range can be ensured while increasing light extraction efficiency.

In FIG. 4C, the organic EL element in the blue sub-pixel region has a peak light extraction efficiency when the second optical length is approximately 210 nm. When the second optical length is from 195 nm to 235 nm, peak values of light extraction efficiency equal to or greater than 90% can be ensured. On the other hand, when the second optical length is from 130 nm to 205 nm, a y value in an appropriate range for the blue sub-pixel (equal to or less than 0.2, preferably equal to or less than 0.18) can be ensured. Note that results around 130 nm are not shown in FIG. 4C. The organic EL element in the blue sub-pixel region preferably has the second optical length set from 195 nm to 205 nm. Thus, chromaticity of emitted light in an appropriate range can be ensured while increasing light extraction efficiency.

FIG. 6 shows results of a more detailed simulation with respect to blue sub-pixels. The upper graph in FIG. 6 shows changes in light extraction efficiency, and the lower graph in FIG. 6 shows changes in chromaticity. As above, when optimizing the second optical length, the first blue light-emitting layer and the second blue light-emitting layer may be considered separately. The solid line in the graph of the upper half of FIG. 6 indicates light extraction efficiency when both the first blue light-emitting layer and the second blue light-emitting layer emit light. The dotted lines in each graph indicate light extraction efficiency when only the first blue light-emitting layer emits light and the second blue light-emitting layer does not emit light. The dashed lines in each graph indicate light extraction efficiency when only the second blue light-emitting layer emits light and the first blue light-emitting layer does not emit light. In each case, the color filter layer is used to correct chromaticity. Thus, when the first blue light-emitting layer and the second blue light-emitting layer both emit light, light extraction efficiency peaks when the second optical length is in a range from 195 nm to 205 nm. When only the second blue light-emitting layer emits light, light extraction efficiency peaks when the second optical length is in a range from 180 nm to 195 nm. When only the first blue light-emitting layer emits light, light extraction efficiency peaks when the second optical length is in a range from 215 nm to 235 nm. In other words, the second optical length that indicates peak light extraction efficiency when both the first blue light-emitting layer and the second blue light-emitting layer emit light is different from the second optical length that indicates peak light extraction efficiency when only the first blue light-emitting layer or only the second blue light-emitting layer emit light. Accordingly, even if the first blue light-emitting layer and

the second blue light-emitting layer are separately optimized, it is not always possible to optimize both light extraction efficiency and chromaticity. According to the present embodiment, the first blue light-emitting layer and the second blue light-emitting layer are both considered at the same time, and therefore a range for the second optical length that optimizes both light extraction efficiency and chromaticity can be obtained.

[5. Optical Design Summary (Top-Emission)]

In the red sub-pixel region 2R, the first optical length is preferably from 20 nm to 50 nm, and the second optical length is preferably from 210 nm to 230 nm. For example, when the first optical length is 30 nm and the second optical length is 220 nm, film thicknesses of each layer may be as follows:

First hole injection layer: 20 nm
First hole transport layer: 10 nm
Red light-emitting layer: 80 nm
First electron transport layer: 40 nm
Charge generating layer: 35 nm
Second hole transport layer: 35 nm

In the green sub-pixel region 2G, the first optical length is preferably from 20 nm to 50 nm, and the second optical length is preferably from 240 nm to 295 nm. For example, when the first optical length is 50 nm and the second optical length is 240 nm, film thicknesses of each layer may be as follows:

First hole injection layer: 35 nm
First hole transport layer: 15 nm
Green light-emitting layer: 80 nm
First electron transport layer: 40 nm
Charge generating layer: 35 nm
Second hole transport layer: 35 nm

In the blue sub-pixel region 2B, the first optical length is preferably from 20 nm to 60 nm, and the second optical length is preferably from 195 nm to 205 nm. For example, when the first optical length is 40 nm and the second optical length is 200 nm, film thicknesses of each layer may be as follows:

First hole injection layer: 30 nm
First hole transport layer: 10 nm
Second blue light-emitting layer: 50 nm
First electron transport layer: 40 nm
Charge generating layer: 35 nm
Second hole transport layer: 35 nm

According to the present embodiment, optical lengths in the red sub-pixel region 2R are within the ranges stated above, and therefore light extraction efficiency of red light emitted from the red light-emitting layer 7R in the red sub-pixel region 2R is improved, while suppressing light extraction efficiency of blue light emitted from the second blue light-emitting layer 11. Further, optical lengths in the green sub-pixel region 2G are within the ranges stated above, and therefore light extraction efficiency of green light emitted from the green light-emitting layer 7G in the green sub-pixel region 2G is improved, while suppressing light extraction efficiency of blue light emitted from the second blue light-emitting layer 11. Further, optical lengths in the blue sub-pixel region 2B are within the ranges stated above, and therefore blue light emitted from both the first blue light-emitting layer 7B and the second blue light-emitting layer 11 can be efficiently extracted externally. Accordingly, current required to obtain a desired luminance is decreased, and therefore lifespan of current-driven organic EL elements can be increased.

According to the present embodiment, the charge generating layer 9 is present in the red sub-pixel region 2R, the

green sub-pixel region 2G, and the blue sub-pixel region 2B. Thus, the charge generating layer 9 can be formed without using a precise shadow mask. Accordingly, manufacturing cost and productivity improvements can be made.

Further, as stated above, preferable ranges for the second optical length are different for each of the red sub-pixel region 2R, the green sub-pixel region 2G, and the blue sub-pixel region 2B. The second optical length may be adjusted for the red sub-pixel region 2R, the green sub-pixel region 2G, and the blue sub-pixel region 2B by making the film thicknesses of the red light-emitting layer 7R, the green light-emitting layer 7G, and the first blue light-emitting layer 7B different from each other. For example, when the red light-emitting layer 7R, the green light-emitting layer 7G, and the first blue light-emitting layer 7B are formed by a wet process such as an inkjet method, film thicknesses can easily be made different from each other.

Further, when one or more layers (according to the present embodiment, the first hole injection layers 5 and the first hole transport layers 6) between the light-reflective electrodes 4 and the first light-emitting layers 7 are referred to as first functional layers, the second optical length may be adjusted for the red sub-pixel region 2R, the green sub-pixel region 2G, and the blue sub-pixel region 2B by making film thicknesses of the first functional layers different from each other. For example, when at least one of the layers included in the first functional layers are formed by a wet process such as an inkjet method, film thicknesses of the first functional layers can easily be made different in each of the sub-pixel regions.

Further, film thicknesses of each layer between the first light-emitting layers 7 and the light-transmissive electrode 13 (according to the present embodiment, the first electron transport layer 8, the charge generating layer 9, the second hole transport layer 10, the second blue light-emitting layer 11, and the second electron transport layer 12) may be the same thicknesses across the red sub-pixel region 2R, the green sub-pixel region 2G, and the blue sub-pixel region 2B. For example, when each layer is formed by vacuum deposition such as by a resistance heating method, thicknesses of each layer in each sub-pixel region becomes equal. [6. Materials of Each Layer (Top-Emission)]

The following gives examples of specific materials of each layer.

<First Substrate>

As an electrically insulative base material of the first substrate 1, glass or plastic may be used, for example. As a glass material, alkali-free glass, soda glass, non-fluorescent glass, phosphoric acid-based glass, boric acid-based glass, quartz glass, etc., may be used. As a plastic material, acrylic resin, styrene resin, polycarbonate resin, epoxy resin, polyethylene, polyester, polyimide, silicone resin, etc., may be used.

<Insulating Layer>

The insulating layer 3 is composed of resin material or inorganic material. As a resin material, a positive type of photosensitive material may be used. As such a photosensitive material, acrylic resin, polyimide resin, siloxane resin, or phenolic resin may be used. As an inorganic material, silicon nitride (SiN), silicon oxynitride (SiON), etc., may be used. The insulating layer 3 may be formed from only resin material, and may be formed from resin material and inorganic material.

<Reflective Electrodes>

The reflective electrodes 4 are composed of a light-reflective electrically-conductive material. As a light-reflective electrically-conductive material, aluminium (Al), alu-

minium alloy, silver (Ag), silver-palladium-copper alloy (APC), silver-rubidium-gold alloy (ARA), molybdenum-chrome alloy (MoCr), nickel and chromium alloy (NiCr), molybdenum (Mo), molybdenum-tungsten alloy (MoW), etc., may be used. The light-reflective electrodes 4 may each contain a layer of a light-transmissive electrically-conductive material and a layer of a light-reflective electrically-conductive material. As a light-transmissive electrically-conductive material, indium tin oxide (ITO) or indium zinc oxide (IZO) may be used.

<Banks>

The banks 2 may be composed of an electrically-insulative resin material. As a resin material of the banks 2, a positive type of photosensitive material may be used. As such a photosensitive material, acrylic resin, polyimide resin, siloxane resin, or phenolic resin may be used.

<First Hole Injection Layers>

As a material of the first hole injection layers 5, a known material may be used. For example, an oxide of silver (Ag), molybdenum (Mo), chromium (Cr), vanadium (V), tungsten (W), nickel (Ni), iridium (Ir), etc., or an electrically conductive polymer such as poly(3,4-ethylenedioxythiophene) polystyrene sulfonate (PEDOT:PSS), or a low-molecular organic compound, polyfluorene, or derivative thereof such as a triazole derivative, an oxadiazole derivative, an imidazole derivative, a polyaryllalkane derivative, a phenylenediamine derivative, an arylamine derivative, an oxazole derivative, a styryl anthracene derivative, a fluorenone derivative, a stilbene derivative, a porphyrin compound, an aromatic tertiary amine compound, a styryl amine compound, etc., or a high-molecular compound such as polyaryllamine or a derivative thereof. In order to further increase hole injectivity, the low-molecular organic compounds listed above may be doped with an electron-accepting material described later.

<First Hole Transport Layers>

The first hole transport layers 6 are intended to promote hole injection from the first hole injection layers 5 to the first light-emitting layers 7 and block escape of electrons and exciton energy from the first light-emitting layers 7. As a material of the first hole transport layers 6, a known material may be used. For example, a material listed above for the first hole injection layers 5 may be used.

<First Light-Emitting Layers>

As a material of the first light-emitting layers 7, a known material may be used. For example, an oxinoid compound, perylene compound, coumarin compound, azacoumarin compound, oxazole compound, oxadiazole compound, perinone compound, pyrrole-pyrrole compound, naphthalene compound, anthracene compound, fluorene compound, fluoranthene compound, tetracene compound, pyrene compound, coronene compound, quinolone compound, azaquinolone compound, pyrazoline derivative, pyrazolone derivative, rhodamine compound, chrysene compound, phenanthrene compound, cyclopentadiene compound, stilbene compound, diphenylquinone compound, styryl compound, butadiene compound, dicyanomethylene pyran compound, dicyanomethylene thiopyran compound, fluorescein compound, pyrylium compound, thiapyrylium compound, selenapyrylium compound, telluropyrylium compound, aromatic aldadiene compound, oligophenylene compound, thioxanthene compound, anthracene compound, cyanine compound, acridine compound, metal complex of a 8-hydroxy quinoline compound, metal complex of a 2-bipyridine compound, complex of Schiff salt and a group III metal, oxine metal complex, fluorescent substance such as a rare earth complex, a low-molecular compound such as a known

phosphorescent material such as a metal complex that phosphoresces such as tris(2-phenylpyridine) iridium, or a high-molecular compound such as polyfluorene, a derivative thereof, polyarylamine, or a derivative thereof. The first light-emitting layers may also be formed from a combination of materials such as a mix of low-molecular material and low-molecular material, high-molecular material and low-molecular material, etc.

<First Electron Transport Layer>

As a material of the first electron transport layer **8**, a known material may be used. For example, an organic material, an alkali metal, an alkaline earth metal, an oxide or fluoride of an alkali metal, or an oxide or fluoride of an alkaline earth metal may be used. As an organic material, an oxydiazole derivative (OXD), triazole derivative (TAZ), phenanthroline derivative (BCP, Bphen), perinone derivative, quinoline complex derivative, silole derivative, dimesityl-boron derivative, triaryl boron derivative, etc., may be used. As an alkali metal or alkaline earth metal, lithium (Li), sodium (Na), cesium (Cs), barium (Ba), or calcium (Ca) may be used. As an oxide or fluoride of an alkali metal or alkaline earth metal, lithium fluoride (LiF), sodium fluoride (NaF), lithium oxide (LiOx), barium oxide (BaOx), cesium carbonate (Cs₂CO₃), etc., may be used. With a view to further improving electron injectability, the organic material may be doped with the alkali metal, the alkaline earth metal, the oxide or fluoride of the alkali metal, the oxide or fluoride of the alkaline earth metal, etc. The first electron transport layer **8** may be formed from a plurality of layers, such as an organic layer and an alkali metal or alkaline earth metal layer, or an organic layer, an oxide or fluoride of an alkali metal or alkaline earth metal layer, or similar.

<Charge Generating Layer>

As a material and a configuration of the charge generating layer **9**, a known material and configuration can be used. For example: an electron-accepting material; an electron-donating material; a layered body or mix of electron-accepting material and electron-donating material; a mix of organic material and electron-accepting material; a mix of organic material and electron-donating material; a layered body of a mix of organic material and electron-accepting material and a mix of organic material and electron-donating material; a layered body or mix of electron-accepting material and a metal or light-transmissive electrode; a layered body or mix of electron-donating material and a metal or light-transmissive electrode; a layered body of a layered body or mix of electron-accepting material and electron-donating material and a metal or light-transmissive electrode; a layered body of a mix of organic material and electron-accepting material and a metal or light-transmissive electrode; a layered body of a mix of organic material and electron-donating material and a metal or light-transmissive electrode; or a layered body of a metal and a light-transmissive electrode may be used.

As an electron-accepting material, an inorganic compound such as iron(III) chloride, iron(III) bromide, iron(III) iodide, gallium iodide, molybdenum oxide, vanadium oxide, or tungsten oxide may be used, or an organic compound such as dichloro-dicyano benzoquinone (DDQ), trinitrofluorenone (TNF), tetracyanoquinodimethane (TCNQ), tetrafluoro-tetracyanoquinodimethane (F₄TCNQ), or a hexaazatriphenylene derivative (for example, HAT-CN6) may be used. As an electron-donating material, an alkali metal or alkaline earth metal such as lithium (Li), sodium (Na), cesium (Cs), barium (Ba), or calcium (Ca) may be used. As an organic material, a material listed for the first hole injection layers **5** or a material listed for the first electron

transport layer **8** may be used. As a metal, a metal thin film of Ag, Au, or Al may be used, for example. As a light-transmissive electrode, indium tin oxide (ITO), indium zinc oxide (IZO), or zinc oxide (ZnO) may be used, for example.

When the first electron transport layer **8** and/or the second hole transport layer **10** include an electron-accepting material and/or electron-donating material, and/or when the charge generating layer **9** includes a metal or light-transmissive electrode, the first electron transport layer **8** and/or the second hole transport layer **10** may be used as a portion of the charge generating layer **9**.

According to the present application, as long as the charge generating layer **9** supplies electrons to the first electron transport layer **8** and supplies holes to the second hole transport layer **10**, the configuration of the charge generating layer **9** should not be construed as being limited to any particular configuration.

According to the present embodiment, the charge generating layer **9** includes hexaazatriphenylene hexacarbonitrile (HAT-CN6), which is an electron-donating material.

<Second Hole Transport Layer>

As a material of the second hole transport layer **10**, a known material may be used. For example, a material listed above for the first hole injection layers **5** may be used.

The second hole transport layer **10** may be formed as one layer, or may be formed with an additional layer. In order to further improve hole injectivity, the second hole transport layer **10** may be doped with an electron-accepting material.

<Second Blue Light-Emitting Layer>

As a material of the second blue light-emitting layer **11**, a known material may be used. For example, a material listed above for the first light-emitting layers **7** may be used. The second blue light-emitting layer **11** may also be formed from a variety of combinations of materials such as a mix of low-molecular material and low-molecular material.

<Second Electron Transport Layer>

As a material of the second electron transport layer **12**, a known material may be used. For example, a material listed above for the first electron transport layer **8** may be used. In order to further improve electron injectability, an organic layer may be doped with an alkali metal, an alkaline earth metal, an oxide of an alkali metal, an oxide of an alkaline earth metal, a fluoride of an alkali metal, a fluoride of an alkaline earth metal, etc. The second electron transport layer **12** may be formed from a plurality of layers, such as an organic layer and an alkali metal or alkaline earth metal layer, or an organic layer, an oxide or fluoride of an alkali metal or alkaline earth metal layer, or similar.

<Light-Transmissive Electrode>

The light-transmissive electrode **13** is composed of a light-transmissive electrically-conductive material. As a light-transmissive electrically-conductive material, indium tin oxide (ITO) or indium zinc oxide (IZO) may be used.

<Protective Layer>

The protective layer **14** is composed of resin material or inorganic material. As an inorganic material, silicon nitride (SiN) or silicon oxynitride (SiON) may be used. As a resin material, a resin adhesive may be used. The protective layer **14** may be a layered body including an inorganic layer and a resin layer.

<Color Filter Layer>

As a material of the color filter layer, a known material may be used.

<Second Substrate>

As a material of the second substrate **16**, glass or plastic may be used, for example. As a glass material, alkali-free glass, soda glass, non-fluorescent glass, phosphoric acid-

based glass, boric acid-based glass, quartz glass, etc., may be used. As a plastic material, acrylic resin, styrene resin, polycarbonate resin, epoxy resin, polyethylene, polyester, polyimide, silicone resin, etc., may be used. When a plastic material is used, the second substrate **16** may include a protective layer for suppressing intrusion of moisture or oxygen.

[7. Organic EL Display Panel Manufacturing Method (Top-Emission)]

A method of manufacturing an organic EL display panel pertaining to the present embodiment is described below, with reference to FIG. 7A, FIG. 7B, FIG. 7C, FIG. 7D, and FIG. 7E.

As shown in FIG. 7A, the insulating layer **3** is formed on the first substrate **1**. The light-reflective electrodes **4** are formed, spaced apart from each other, on the insulating layer **3**. The light-reflective electrodes **4** can, for example, be formed by forming an electrically-conductive film including a light-reflective electrically-conductive material on the insulating layer **3** by sputtering, then patterning the electrically-conductive film by etching.

As shown in FIG. 7B, the banks **2** are formed on the first substrate **1**. The banks **2** can be formed by forming a photosensitive layer from a photosensitive material on the insulating layer **3**, exposing the photosensitive layer to light through a photomask, and developing the photosensitive layer that is exposed to light. When the first hole injection layers **5**, the first hole transport layers **6**, and the first light-emitting layers **7** are formed by wet processes, the banks **2** function as structures for preventing overflow of applied ink.

As shown in FIG. 7C, the first hole injection layers **5**, the first hole transport layers **6**, the red light-emitting layer **7R**, the green light-emitting layer **7G**, and the first blue light-emitting layer **7B** are formed. These layers can, for example, be formed by using wet processes such as an inkjet method.

As shown in FIG. 7D, the first electron transport layer **8**, the charge generating layer **9**, the second hole transport layer **10**, the second blue light-emitting layer **11**, and the second electron transport layer **12** are formed. These layers can, for example, be formed by using a vacuum deposition method such as a resistance heating method.

As shown in FIG. 7E, the light-transmissive electrode **13** is formed. This layer can, for example, be formed by using a vacuum deposition method such as a resistance heating method, or a dry method such as sputtering, reactive sputtering, or ion plating. Subsequently, the protective layer **14** is formed, and the protective layer **14** is covered by the color filter layer **15** and the second substrate **16**.

[8. Configuration of Organic EL Display Panel (Bottom-Emission)]

A configuration of an organic EL display panel pertaining to Embodiment 2 of the present disclosure is described below, with reference to FIG. 8. FIG. 8 is a cross-section enlargement of a pixel of an organic EL display panel pertaining to Embodiment 2 of the present disclosure. According to the present embodiment, an organic EL display panel **200** is a so-called "bottom-emission" type, in which a display surface thereof is towards the lower side of FIG. 8.

The organic EL display panel **200** includes the second substrate **16**, the color filter **15**, the banks **2**, the insulating layer **3**, light-transmissive electrodes **213**, the first hole injection layers **5**, the first hole transport layers **6**, the red light-emitting layer **7R**, the green light-emitting layer **7G**, the first blue light-emitting layer **7B**, the first electron transport layer **8**, the charge generating layer **9**, the second hole transport layer **10**, the second blue light-emitting layer

11, the second electron transport layer **12**, a light-reflective electrode **204**, the protective layer **14**, and the second substrate **1**. The functions of each layer, materials, and method of manufacture are the same as for Embodiment 1, and therefore description thereof is not repeated here.

[9. Optical Design (Bottom-Emission)]

FIG. 9 illustrates optical paths of light emitted from the organic EL elements in sub-pixel regions.

An optical path **C1a** is an optical path of light travelling from one of the first light-emitting layers **7**, towards one of the light-transmissive electrodes **213**, without travelling towards the light-reflective electrode **204**. An optical path **C1b** is an optical path of light travelling from one of the first light-emitting layers **7** towards the light-reflective electrode **204**, being reflected at the light-reflective electrode **204**, and subsequently travelling towards one of the light-transmissive electrodes **213**. An optical path **C2a** is an optical path of light travelling from the second blue light-emitting layer **11**, towards one of the light-transmissive electrodes **213**, without travelling towards the light-reflective electrode **204**. An optical path **C2b** is an optical path of light travelling from the second blue light-emitting layer **11** towards the light-reflective electrode **204**, being reflected at the light-reflective electrode **204**, and subsequently travelling towards one of the light-transmissive electrodes **213**.

According to the present embodiment, when designing microcavity structure of an organic EL element, it is sufficient to consider optical lengths **L1R**, **L1G**, **L1B** (hereinafter, "first optical lengths") between the light-emitting surfaces **7a** of the first light-emitting layers **7** and light reflecting surfaces **204a** of the light-reflective electrode **204** and optical lengths **L2R**, **L2G**, **L2B** (hereinafter, "second optical lengths") between the light-emitting surfaces **11a** of the second blue light-emitting layer **11** and the light reflecting surfaces **204a** of the light-reflective electrode **204**.

[10. Second Optical Lengths (Bottom-Emission)]

According to the present embodiment, the first hole injection layers **5**, the first hole transport layers **6**, the red light-emitting layer **7R**, the green light-emitting layer **7G**, and the first blue light-emitting layer **7B** are described as being formed by wet processes. Further, the first electron transport layer **8**, the charge generating layer **9**, the second hole transport layer **10**, the second blue light-emitting layer **11**, and the second electron transport layer **12** are described as being formed by vacuum deposition. Further, a shadow mask is not used in the vacuum deposition. In this case, the second optical lengths are the same for each of the red sub-pixel region **2R**, the green sub-pixel region **2G**, and the blue sub-pixel region **2B**.

FIG. 10 shows optical simulation results, and indicates changes in light extraction efficiency and chromaticity of organic EL elements with respect to the second optical lengths. Light extraction efficiency indicates a value prior to light absorption by the color filter layer, i.e., a value of light emitted from a second blue light-emitting layer. Base values for film thickness of each layer were set as follows:

Light transmissive electrodes: 50 nm (ITO)

First hole injection layers: 25 nm (electrically conductive polymer material)

First hole transport layers: 20 nm (amine compound)

First light-emitting layers: 70 nm (polyfluorene derivative)

First electron transport layer: 35 nm (phenanthroline derivative)

Charge generating layer: 10 nm (HAT-CN6)

Second hole transport layer: 25 nm (amine compound)

Second blue light-emitting layer: 25 nm (anthracene compound)

Second electron transport layer: 35 nm (phenanthroline derivative)

Light-reflective electrode: 120 nm (aluminium)

Refractive indices of the materials were evaluated by spectroscopic ellipsometry.

According to the present embodiment, second optical lengths are represented by the sum of film thicknesses of the second electron transport layer and the second blue light-emitting layer. FIG. 10 shows cases in which film thicknesses of the second electron transport layers are varied (dashed lines) and cases in which film thicknesses of the second blue light-emitting layers are varied (solid lines). Because both materials are organic materials, they have substantially the same refractive indices. Thus, it can be seen that changes in either film thickness shows the same trends. In other words, film thickness of any layer between the light reflecting surfaces of a light-reflective electrode and light-emitting surfaces of the second blue light-emitting layer may be adjusted, and a layer such as the second hole injection layer may be added.

In FIG. 10, the organic EL element in each sub-pixel region has a peak light extraction efficiency when the second optical length is approximately 70 nm. When the second optical length is from 60 nm to 80 nm, peak values of light extraction efficiency equal to or greater than 90% can be ensured. On the other hand, it can be seen that chromaticity of emitted light worsens (increases) as the second optical length increases. To emit light as blue light, a y value of 0.20 or less is preferable. A y value of 0.20 or less can be ensured as long as the second optical length is 75 nm or less. Accordingly, a second optical length from 60 nm to 75 nm is preferable. Thus, chromaticity of emitted light in a blue range can be ensured while increasing light extraction efficiency.

[11. First Optical Lengths (Bottom-Emission)]

FIG. 11A, FIG. 11B, and FIG. 11C show optical simulation results, and indicate changes in light extraction efficiency and chromaticity of organic EL elements with respect to the first optical lengths. FIG. 11A indicates a red sub-pixel, FIG. 11B indicates a green sub-pixel, and FIG. 11C indicates a blue sub-pixel. Light extraction efficiency indicates a value prior to light absorption by the color filter layer, i.e., a value with respect to the sum of light emitted from a first light-emitting layer and light emitted from the second blue light-emitting layer. Base values for film thickness of each layer were set as follows:

Light transmissive electrodes: 50 nm (ITO)

First hole injection layers: 25 nm (electrically conductive polymer material)

First hole transport layers: 20 nm (amine compound)

First light-emitting layers: 70 nm (polyfluorene derivative)

First electron transport layer: 35 nm (phenanthroline derivative)

Charge generating layer: 10 nm (HAT-CN6)

Second hole transport layer: 25 nm (amine compound)

Second blue light-emitting layer: 25 nm (anthracene compound)

Second electron transport layer: 35 nm (phenanthroline derivative)

Light-reflective electrode: 120 nm (aluminium)

Refractive indices of the materials were evaluated by spectroscopic ellipsometry.

According to the present embodiment, the first optical lengths are represented by the sum of film thicknesses of the

second electron transport layer, the second blue light-emitting layer, the second hole transport layer, the charge generating layer, the first electron transport layer, and one of the first light-emitting layers. In this example, aside from the first light-emitting layers, film thickness in each sub-pixel region cannot be varied as layers are formed by dry processes that do not use a shadow mask. The first light-emitting layers are formed by wet processes and can therefore be implemented with different film thicknesses for each sub-pixel region. FIG. 11A, FIG. 11B, and FIG. 11C show optical simulation data (solid lines) indicating changes in light extraction efficiency and chromaticity when film thickness of one of the first light-emitting layers is changed, and show experimental data (points) indicating properties of actually produced organic EL elements. A close match is shown between the optical simulations and the experimental data, indicating that predictions made based on the optical simulations are reliable.

In FIG. 11A, the organic EL element in the red sub-pixel region has a peak light extraction efficiency when the first optical length is approximately 290 nm. When the first optical length is from 255 nm to 315 nm, peak values of light extraction efficiency equal to or greater than 90% can be ensured. However, when the first optical length is 300 nm or greater, thickness of the red light-emitting layer becomes 170 nm or greater, and the drive voltage of the organic EL element becomes very high. Accordingly, the organic EL element in the red sub-pixel region preferably has the first optical length set from 255 nm to 300 nm. FIG. 12A shows a light emission spectrum when the first optical length is 210 nm, and FIG. 12B shows a light emission spectrum when the first optical length is 290 nm. It can be seen that when the first optical length is 210 nm, blue light emission is very strong, and when the first optical length is 290 nm, red light emission is strong and blue light emission is suppressed. Accordingly, by limiting the first optical length to the range described above, unwanted blue light emission can be suppressed and red light emission can be strongly extracted, and as a result, chromaticity of emitted light in an appropriate range can be ensured and light extraction efficiency can be increased.

FIG. 13 shows results of a more detailed simulation with respect to red sub-pixels. The upper graph in FIG. 13 shows changes in light extraction efficiency, and the lower graph in FIG. 13 shows changes in chromaticity. When color correction using the color filter layer is implemented (solid line), light extraction efficiency peaks when the first optical length is approximately 270 nm. When the first optical length is from 255 nm to 300 nm, a high light extraction efficiency can be maintained when color correction is implemented using a color filter.

Further, as described with respect to Embodiment 1, when optimizing the first optical length, the red light-emitting layer and the second blue light-emitting layer may be considered separately. The solid line in the graph of the upper half of FIG. 13 indicates light extraction efficiency when both the red light-emitting layer and the second blue light-emitting layer emit light. The dashed lines in each graph indicate light extraction efficiency when only the red light-emitting layer emits light and the second blue light-emitting layer does not emit light. In each case, color correction is implemented by using a color filter layer. Thus, when the red light-emitting layer and the second blue light-emitting layer both emit light, light extraction efficiency peaks when the second optical length is in a range from 255 nm to 300 nm. When only the red light-emitting layer emits light, light extraction efficiency peaks when the

first optical length is in a range from 300 nm to 320 nm. In other words, the first optical length that indicates peak light extraction efficiency when both the red light-emitting layer and the second blue light-emitting layer emit light is different from the first optical length that indicates peak light extraction efficiency when only the red light-emitting layer emits light. Accordingly, even if the red light-emitting layer and the second blue light-emitting layer are separately optimized, it is not always possible to optimize both light extraction efficiency and chromaticity. According to the present embodiment, the red light-emitting layer and the second blue light-emitting layer are both considered at the same time, and therefore a range for the first optical length that optimizes both light extraction efficiency and chromaticity can be obtained.

In FIG. 11B, the organic EL element in the green sub-pixel region has a peak light extraction efficiency when the first optical length is approximately 270 nm. When the first optical length is from 250 nm to 300 nm, peak values of light extraction efficiency equal to or greater than 90% can be ensured. Further, in this range, a y value in an appropriate range for the green sub-pixel (y value equal to or greater than 0.50) can be ensured. Accordingly, a first optical length from 250 nm to 300 nm is preferable. Thus, chromaticity of emitted light in an appropriate range can be ensured while increasing light extraction efficiency.

In FIG. 11C, the organic EL element in the blue sub-pixel region has a peak light extraction efficiency when the first optical length is approximately 230 nm. When the first optical length is from 210 nm to 250 nm, peak values of light extraction efficiency equal to or greater than 90% can be ensured. When the first optical length is equal to or less than 220 nm, a y value in an appropriate range for the blue sub-pixel (y value equal to or less than 0.2, even more preferably equal to or less than 0.18) can be ensured. Accordingly, the organic EL element in the blue sub-pixel region preferably has the first optical length set from 210 nm to 220 nm. Thus, chromaticity of emitted light in an appropriate range can be ensured while increasing light extraction efficiency.

FIG. 14 shows results of a more detailed simulation with respect to blue sub-pixels. The upper graph in FIG. 14 shows changes in light extraction efficiency, and the lower graph in FIG. 14 shows changes in chromaticity. As above, when optimizing the first optical length, the first blue light-emitting layer and the second blue light-emitting layer may be considered separately. The solid line in the graph of the upper half of FIG. 14 indicates light extraction efficiency when both the first blue light-emitting layer and the second blue light-emitting layer emit light. The dotted lines in each graph indicate light extraction efficiency when only the first blue light-emitting layer emits light and the second blue light-emitting layer does not emit light. The dashed lines in each graph indicate light extraction efficiency when only the second blue light-emitting layer emits light and the first blue light-emitting layer does not emit light. In each case, the color filter layer is used to correct chromaticity. Thus, when the first blue light-emitting layer and the second blue light-emitting layer both emit light, light extraction efficiency peaks when the first optical length is in a range from 210 nm to 220 nm. When only the first blue light-emitting layer emits light, light extraction efficiency peaks when the first optical length is in a range from 195 nm to 210 nm. When only the second blue light-emitting layer emits light, light extraction efficiency peaks when the first optical length is in a range from 220 nm to 240 nm. In other words, the first optical length that indicates peak light extraction efficiency

when both the first blue light-emitting layer and the second blue light-emitting layer emit light is different from the first optical length that indicates peak light extraction efficiency when only the first blue light-emitting layer emits light or when only the second blue light-emitting layer emits light. Accordingly, even if the first blue light-emitting layer and the second blue light-emitting layer are separately optimized, it is not always possible to optimize both light extraction efficiency and chromaticity. According to the present embodiment, the first blue light-emitting layer and the second blue light-emitting layer are both considered at the same time, and therefore a range for the second optical length that optimizes both light extraction efficiency and chromaticity can be obtained.

[12. Optical Design Summary (Bottom-Emission)]

In the red sub-pixel region 2R, the first optical length is preferably from 255 nm to 300 nm, and the second optical length is preferably from 60 nm to 75 nm. For example, when the first optical length is 290 nm and the second optical length is 60 nm, film thicknesses of each layer may be as follows:

Red light-emitting layer: 160 nm
First electron transport layer: 35 nm
Charge generating layer: 10 nm
Second hole transport layer: 25 nm
Second blue light-emitting layer: 25 nm
Second electron transport layer: 35 nm

In the green sub-pixel region 2G, the first optical length is preferably from 250 nm to 300 nm, and the second optical length is preferably from 60 nm to 75 nm. For example, when the first optical length is 290 nm and the second optical length is 60 nm, film thicknesses of each layer may be as follows:

Green light-emitting layer: 160 nm
First electron transport layer: 35 nm
Charge generating layer: 10 nm
Second hole transport layer: 25 nm
Second blue light-emitting layer: 25 nm
Second electron transport layer: 35 nm

In the blue sub-pixel region 2B, the first optical length is preferably from 210 nm to 220 nm, and the second optical length is preferably from 60 nm to 75 nm. For example, when the first optical length is 215 nm and the second optical length is 60 nm, film thicknesses of each layer may be as follows:

First blue light-emitting layer: 85 nm
First electron transport layer: 35 nm
Charge generating layer: 10 nm
Second hole transport layer: 25 nm
Second blue light-emitting layer: 25 nm
Second electron transport layer: 35 nm

According to the present embodiment, as with Embodiment 1, light extraction efficiency of unwanted blue light can be suppressed in the red sub-pixel region 2R and the green sub-pixel region 2G, and blue light can be efficiently extracted from the blue sub-pixel region 2B.

According to the present embodiment, as with Embodiment 1, the charge generating layer 9 is present in the red sub-pixel region 2R, the green sub-pixel region 2G, and the blue sub-pixel region 2B. Thus, the charge generating layer 9 can be formed without using a precise shadow mask. Accordingly, manufacturing cost and productivity improvements can be made.

[13. Display Device]

The organic EL display panel described as Embodiment 1 and as Embodiment 2 can be used in a display device 1000 as illustrated in FIG. 15. As illustrated in FIG. 16, the display

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device **1000** includes an organic EL display panel **100** and a drive control circuit **1017**. The organic EL display panel **100** is, for example, the organic EL display panel described as Embodiment 1. The drive control circuit **1017** includes a drive circuits **1018, 1019, 1020, 1021** and a control circuit **1022**. The control circuit **1022** receives a video signal from an external source, and converts the video signal to voltage signals appropriate to TFT drive circuits in the organic EL display panel **100**. The drive circuits **1018, 1019, 1020, 1021** transmit the voltage signals received from the control circuit to the TFT drive circuits in the organic EL display panel **100**.

INDUSTRIAL APPLICABILITY

The organic EL display panel pertaining to the present disclosure can be used, for example, in the home, in public facilities, or in businesses, and can be used in a variety of display devices, television devices, display devices for portable electronic devices, etc.

REFERENCE SIGNS LIST

- 1 first substrate
- 2 banks
- 3 insulating layer
- 4, 204 light-reflecting electrodes
- 5 first hole injection layers
- 6 first hole transport layers
- 7 first light-emitting layers
- 7R red light-emitting layer
- 7G green light-emitting layer
- 7B first blue light-emitting layer
- 8 first electron transport layer
- 9 charge generating layer
- 10 second hole transport layer
- 11 second blue light-emitting layer
- 12 second electron transport layer
- 13, 213 light-transmissive electrodes
- 14 protective layer
- 15 color filter layer
- 15R red filter
- 15G green filter
- 15B blue filter
- 16 second substrate
- 17R first red light-emitting unit
- 17G first green light-emitting unit
- 17B first blue light-emitting unit
- 18B second blue light-emitting unit

The invention claimed is:

1. An organic electroluminescence (EL) display panel comprising:

- a substrate;
- a plurality of banks, disposed above the substrate, that define a red sub-pixel region, a green sub-pixel region, and a blue sub-pixel region;
- a plurality of light-reflective electrodes, disposed above the substrate in the red sub-pixel region, the green sub-pixel region, and the blue sub-pixel region, each of the light-reflective electrodes having a light-reflective surface;
- a first red light-emitting unit disposed above a first one of the light-reflective electrodes in the red sub-pixel region, the first red light-emitting unit including a red light-emitting layer comprising a material that has an emission peak in a red wavelength band, the red

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light-emitting layer having a light-emitting surface that faces the light-reflective surface of the first one of the light-reflective electrodes;

- a first green light-emitting unit disposed above a second one of the light-reflective electrodes in the green sub-pixel region, the first green light-emitting unit including a green light-emitting layer comprising a material that has an emission peak in a green wavelength band, the green light-emitting layer having a light-emitting surface that faces the light-reflective surface of the second one of the light-reflective electrodes;
 - a first blue light-emitting unit disposed above a third one of the light-reflective electrodes in the blue sub-pixel region, the first blue light-emitting unit including a first blue light-emitting layer comprising a material that has an emission peak in a blue wavelength band, the first blue light-emitting layer having a light-emitting surface that faces the light-reflective surface of the third one of the light-reflective electrodes;
 - a charge generating layer disposed above the first red light-emitting unit, the first green light-emitting unit, and the first blue light-emitting unit in the red sub-pixel region, the green sub-pixel region, and the blue sub-pixel region;
 - a second blue light-emitting unit disposed above the charge generating layer in the red sub-pixel region, the green sub-pixel region, and the blue sub-pixel region, the second blue light-emitting unit including a second blue light-emitting layer comprising a material that has an emission peak in a blue wavelength band, the second blue light-emitting layer having light-emitting surfaces that each face corresponding ones of the light-reflective surfaces of the light-reflective electrodes; and
 - a light-transmissive electrode disposed above the second blue light-emitting unit in the red, the green and the blue sub-pixel regions, wherein
 - in the red sub-pixel region, an optical length between the light-emitting surface of the red light-emitting layer and the light-reflective surface of the first one of the light-reflective electrodes is from 20 nm to 50 nm,
 - in the green sub-pixel region, an optical length between the light-emitting surface of the green light-emitting layer and the light-reflective surface of the second one of the light-reflective electrodes is from 20 nm to 50 nm,
 - in the blue sub-pixel region, an optical length between the light-emitting surface of the first blue light-emitting layer and the light-reflective surface of the third one of the light-reflective electrodes is from 20 nm to 60 nm,
 - in the red sub-pixel region, an optical length between one of the light-emitting surfaces of the second blue light-emitting layer and the light-reflective surface of the first one of the light-reflective electrodes is from 210 nm to 230 nm,
 - in the green sub-pixel region, an optical length between one of the light-emitting surfaces of the second blue light-emitting layer and the light-reflective surface of the second one of the light-reflective electrodes is from 240 nm to 295 nm,
 - in the blue sub-pixel region, an optical length between one of the light-emitting surfaces of the first blue light-emitting layer and the light-reflective surface of the third one of the light-reflective electrodes is from 195 nm to 205 nm.
2. The organic EL display panel of claim 1, further comprising:

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a color filter layer that includes a red filter disposed above the first one of the light-reflective electrodes in the red sub-pixel region, a green filter disposed above the second one of the light-reflective electrodes in the green sub-pixel region, and a blue filter disposed above the third one of the light-reflective electrodes in the blue sub-pixel region.

3. The organic EL display panel of claim 1, wherein the red light-emitting layer, the green light-emitting layer, and the first blue light-emitting layer have different thicknesses from each other.

4. The organic EL display panel of claim 1, wherein the first red light-emitting unit includes a first functional layer between the first one of the light-reflective electrodes and the red light-emitting layer, the first green light-emitting unit includes a first functional layer between the second one of the light-reflective electrodes and the green light-emitting layer, and the first blue light-emitting unit includes a first functional layer between the third one of the light-reflective electrodes and the first blue light-emitting layer,

the first functional layer of the first red light-emitting unit, the first functional layer of the first green light-emitting unit, and the first functional layer of the first blue light-emitting unit are separated from each other by the plurality of the banks, and have different thicknesses from each other.

5. A display device comprising the organic EL display panel of claim 1, and drive control circuitry that drives the organic EL display panel.

6. An organic electroluminescence (EL) display panel comprising:

a substrate;

a plurality of banks, disposed above the substrate, that define a red sub-pixel region, a green sub-pixel region, and a blue sub-pixel region;

a plurality of light-transmissive electrodes, disposed above the substrate in the red sub-pixel region, the green sub-pixel region, and the blue sub-pixel region; a first red light-emitting unit disposed above a first one of the light-transmissive electrodes in the red sub-pixel region, the first red light-emitting unit including a red light-emitting layer comprising a material that has an emission peak in a red wavelength band, the red light-emitting layer having a light-emitting surface that faces the first one of the light-transmissive electrodes;

a first green light-emitting unit disposed above a second one of the light-transmissive electrodes in the green sub-pixel region, the first green light-emitting unit including a green light-emitting layer comprising a material that has an emission peak in a green wavelength band, the green light-emitting layer having a light-emitting surface that faces the second one of the light-transmissive electrodes;

a first blue light-emitting unit disposed above a third one of the light-transmissive electrodes in the blue sub-pixel region, the first blue light-emitting unit including a first blue light-emitting layer comprising a material that has an emission peak in a blue wavelength band, the first blue light-emitting layer having a light-emitting surface that faces the third one of the light-transmissive electrodes;

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a charge generating layer disposed above the first red light-emitting unit, the first green light-emitting unit, and the first blue light-emitting unit in the red sub-pixel region, the green sub-pixel region, and the blue sub-pixel region;

a second blue light-emitting unit disposed above the charge generating layer in the red sub-pixel region, the green sub-pixel region, and the blue sub-pixel region, the second blue light-emitting unit including a second blue light-emitting layer comprising a material that has an emission peak in a blue wavelength band, the second blue light-emitting layer having light-emitting surfaces that each face corresponding ones of the light-transmissive electrodes; and

a light-reflective electrode disposed above the second blue light-emitting unit in the red sub-pixel region, the green sub-pixel region, and the blue sub-pixel region, the light-reflective electrode having a plurality of light-reflecting surfaces, wherein

in the red sub-pixel region, an optical length between the light-emitting surface of the red light-emitting layer and a corresponding one of the light-reflective surfaces of the light-reflective electrode is from 255 nm to 300 nm,

in the green sub-pixel region, an optical length between the light-emitting surface of the green light-emitting layer and a corresponding one of the light-reflective surfaces of the light-reflective electrode is from 250 nm to 300 nm,

in the blue sub-pixel region, an optical length between the light-emitting surface of the first blue light-emitting layer and a corresponding one of the light-reflective surfaces of the light-reflective electrode is from 210 nm to 220 nm, and

in the red sub-pixel region, the green sub-pixel region, and the blue sub-pixel region, each optical length between the light-emitting surfaces of the second blue light-emitting layer and corresponding ones of the light-reflective surfaces of the light-reflective electrode is from 60 nm to 75 nm.

7. The organic EL display panel of claim 6, further comprising:

a color filter layer that includes a red filter disposed below the first one of the light-transmissive electrodes in the red sub-pixel region, a green filter disposed below the second one of the light-transmissive electrodes in the green sub-pixel region, and a blue filter disposed below the third one of the light-transmissive electrodes in the blue sub-pixel region.

8. The organic EL display panel of claim 6, wherein the red light-emitting layer, the green light-emitting layer, and the first blue light-emitting layer have different thicknesses from each other.

9. A method of manufacturing the organic electroluminescence (EL) display panel of claim 1, the method comprising:

creating the red light-emitting layer, the green light-emitting layer, and the first blue light-emitting layer by using a wet process, and

creating the second blue light-emitting layer by using vacuum deposition or sputtering.

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专利名称(译)	具有第二蓝色发光体的有机EL显示面板，由其提供的显示装置，以及用于制造有机EL显示面板的方法		
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摘要(译)

一种有机EL显示面板，包括光反射电极，红色发光层，绿色发光层，第一蓝色发光层，电荷产生层，第二蓝色发光层和光-透射电极。在红色子像素区域中，第一光学长度为20nm至50nm，第二光学长度为210nm至230nm。在绿色子像素区域中，第一光学长度为20nm至50nm，第二光学长度为240nm至295nm。在蓝色子像素区域中，第一光学长度为20nm至60nm，第二光学长度为195nm至205nm。

